



MP4317

45V, 7A, Low I_Q , Synchronous Step-Down Converter with Frequency Spread Spectrum

DESCRIPTION

The MP4317 is a configurable-frequency, synchronous, step-down switching converter with integrated internal high-side and low-side power MOSFETs (HS-FET and LS-FET, respectively). It can achieve up to 7A of highly efficient output current (I_{OUT}) with current mode control for fast loop response.

The wide 3.3V to 45V input voltage (V_{IN}) range accommodates a variety of step-down applications in automotive input environments. High duty cycle and low-dropout mode are provided for automotive cold-crank conditions. The 1.7 μ A shutdown current (I_{SD}) allows the device to be used in battery-powered applications.

High power conversion efficiency across the entire load range is achieved by scaling down the switching frequency (f_{SW}) under light-load conditions. This reduces switching and gate driver losses.

An open-drain power good (PG) signal indicates whether the output is within 95% to 105% of its nominal voltage.

Frequency foldback prevents inductor current (I_L) runaway during start-up. Thermal shutdown provides reliable, fault-tolerant operation.

The MP4317 is available in a QFN-20 (4mmx4mm) package.

FEATURES

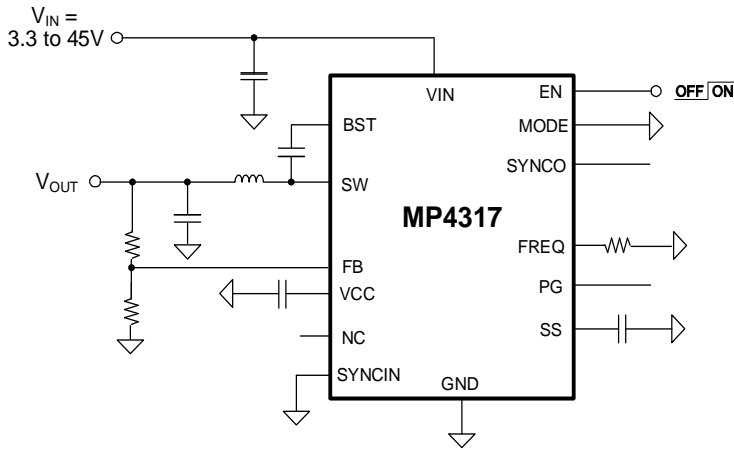
- Wide 3.3V to 45V Operating Input Voltage (V_{IN}) Range
- Up to 7A Continuous Output Current (I_{OUT})
- 1.7 μ A Low Shutdown Current (I_{SD})
- 18 μ A Sleep Mode Quiescent Current (I_Q)
- 48m Ω /20m Ω Internal Power MOSFETs
- 350kHz to 1000kHz Configurable Switching Frequency (f_{SW}) for Car Battery Applications
- Can Be Synchronized to an External Clock
- Out-of-Phase Synchronized Clock Output
- Frequency Spread Spectrum (FSS) for Low Electromagnetic Interference (EMI)
- Symmetric V_{IN} for Low EMI
- Power Good (PG) Output
- External Soft Start (SS)
- 100ns Minimum On Time (t_{ON_MIN})
- Selectable Advanced Asynchronous Modulation (AAM) Mode or Forced Continuous Conduction Mode (FCCM)
- Low-Dropout Mode
- Over-Current Protection (OCP) with Hiccup Mode
- Available in a QFN-20 (4mmx4mm) Package
- Available in a Wettable Flank Package

APPLICATIONS

- Radios
- Battery-Powered Systems
- General-Purpose Consumer Applications
- Industrial Power Systems

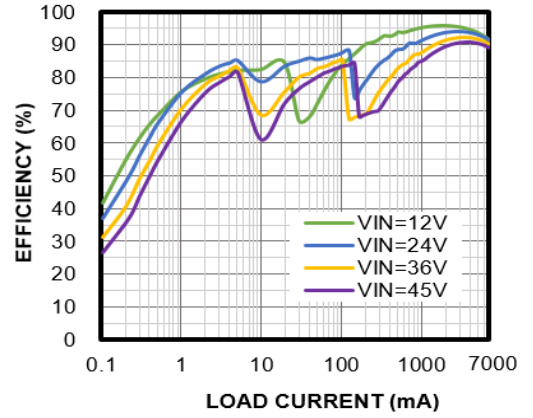
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TYPICAL APPLICATION



Efficiency vs. Load Current

V_{OUT} = 5V, f_{sw} = 470kHz, L = 4.7μH,
DCR = 15mΩ, AAM mode



ORDERING INFORMATION

| Part Number* | Package | Top Marking | MSL Rating** |
|--------------|------------------|-------------|--------------|
| MP4317GRE*** | QFN-20 (4mmx4mm) | See Below | 1 |

* For Tape & Reel, add suffix -Z (e.g. MP4317GRE-Z).

** Moisture Sensitivity Level Rating

*** Wettable Flank

TOP MARKING

MPSYWW

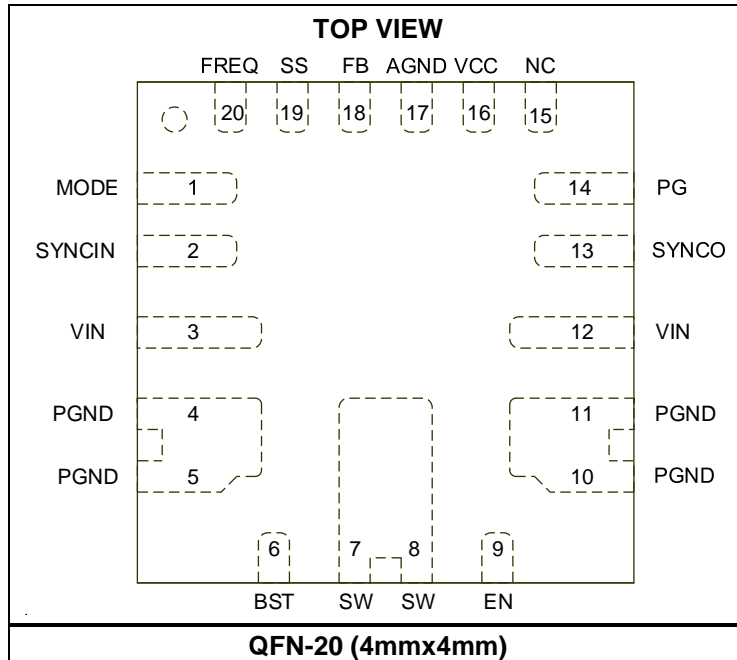
MP4317

LLLLLL

E

MPS: MPS prefix
 Y: Year code
 WW: Week code
 MP4317: Part number
 LLLLLL: Lot number
 E: Wettable flank

PACKAGE REFERENCE



PIN FUNCTIONS

| Pin # | Name | Description |
|--------------|--------|--|
| 1 | MODE | Mode selection. Pull the MODE pin high to make the converter operate in forced continuous conduction mode (FCCM). Pull MODE low to make the converter operate in advanced asynchronous modulation (AAM) mode. Do not float MODE. |
| 2 | SYNCIN | Synchronous input. Apply a 350kHz to 1000kHz clock signal to the SYNCIN pin to synchronize the internal oscillator frequency to the external clock. SYNCIN has an internal high impedance (Hi-Z). If using SYNCIN, ensure that the external SYNC clock has an adequate pull-up and pull-down resistance. If the external clock's pull-down resistance is not sufficient, or if SYNCIN enters a Hi-Z state, place a $\leq 51\text{k}\Omega$ resistor between the SYNCIN pin and AGND. Do not float SYNCIN. |
| 3, 12 | VIN | Input supply. The VIN pin powers the internal circuitry and the high-side MOSFET (HS-FET) connected to the SW pin. To minimize switching spikes at the input, connect a decoupling capacitor between the VIN pin and PGND. Place this capacitor close to VIN. |
| 4, 5, 10, 11 | PGND | Power ground. |
| 6 | BST | Bootstrap. The BST pin is the positive power supply for the HS-FET driver. Connect a bypass capacitor between the BST and SW pins. For more information, see the Selecting the External Bootstrap (BST) Diode and Resistor section on page 32. |
| 7, 8 | SW | Switch output. The SW pin is the output of the internal power MOSFETs. |
| 9 | EN | Enable. Pull the EN pin above 1V to turn the converter on; pull EN below 0.85V to turn it off. |
| 13 | SYNCO | Synchronous output. The SYNCO pin outputs a clock that is 180° out of phase with the internal oscillator. SYNCO can also output a signal opposite of the clock applied at the SYNCIN pin. Float SYNCO if not used. |
| 14 | PG | Power good indicator. The PG pin is an open-drain output. Connect PG to a power source via a pull-up resistor. If the output voltage (V_{OUT}) is between 95% and 105% of the nominal voltage, PG is pulled high. If V_{OUT} exceeds 106.5% or drops below 93% of the nominal voltage, PG is pulled low. |
| 15 | NC | Not connected. |
| 16 | VCC | Bias supply. The VCC pin supplies 4.9V to the internal control circuit and gate drivers. Connect a decoupling capacitor from VCC to AGND. Place this capacitor close to VCC. For more information, see the Selecting the VCC Capacitor (C_{VCC}) section on page 32. |
| 17 | AGND | Analog ground. |
| 18 | FB | Feedback input. To set V_{OUT} , connect the FB pin to the center of the external resistor divider. Place the resistor divider as close to FB as possible. Keep vias away from the FB traces. The feedback voltage (V_{FB}) threshold is 0.815V. |
| 19 | SS | Soft-start input. Place a capacitor between the SS pin and AGND to set the soft-start time (t_{SS}). During start-up, SS provides 13 μ A to the soft-start capacitor (C_{SS}). As the SS voltage (V_{SS}) increases, V_{FB} increases to limit the input inrush current during start-up. |
| 20 | FREQ | Switching frequency setting. Connect a resistor from the FREQ pin to AGND to set the switching frequency (f_{SW}). For more information, see the f_{SW} vs. R_{FREQ} curves on page 15. |

ABSOLUTE MAXIMUM RATINGS ⁽¹⁾

| | |
|---|-------------------------------------|
| VIN, EN | -0.3V to +50V |
| SW | -0.3V to V _{IN_MAX} + 0.3V |
| BST | V _{SW} + 5.5V |
| All other pins..... | -0.3V to +5.5V |
| Continuous power dissipation (T _A = 25°C) ^{(2) (5)} | |
| QFN-20 (4mmx4mm)..... | 5.4W |
| Operating junction temperature..... | 150°C |
| Lead temperature | 260°C |
| Storage temperature..... | -65°C to +150°C |

ESD Ratings

| | |
|---------------------------------|-------|
| Human body model (HMB) | ±2kV |
| Charged device model (CDM)..... | ±750V |

Recommended Operating Conditions

| | |
|---|----------------------------------|
| Supply voltage (V _{IN}) | 3.3V to 45V |
| Output voltage (V _{OUT})..... | 0.815V to 0.95 x V _{IN} |
| Operating junction temp (T _J) | -40°C to +125°C ⁽³⁾ |

| Thermal Resistance | θ_{JA} | θ_{JC} |
|------------------------------------|-----------------------|-----------------------|
| QFN-20 (4mmx4mm) | | |
| JESD51-7 ⁽⁴⁾ | 44..... | 9..... °C/W |
| EVQ4317-R-00A ⁽⁵⁾ | 23..... | 2.5... °C/W |

Notes:

- 1) Exceeding these ratings may damage the device.
- 2) The maximum allowable power dissipation is a function of the maximum junction temperature T_J (MAX), the junction-to-ambient thermal resistance θ_{JA}, and the ambient temperature T_A. The maximum allowable continuous power dissipation at any ambient temperature is calculated by P_D (MAX) = (T_J (MAX) - T_A) / θ_{JA}. Exceeding the maximum allowable power dissipation can cause excessive die temperature, and the converter may go into thermal shutdown. Internal thermal shutdown circuitry protects the device from permanent damage.
- 3) Operating junction temperatures above 125°C may be supported. Contact MPS for more details.
- 4) Measured on JESD51-7, 4-layer PCB. The values given in this table are only valid for comparison with other packages and cannot be used for design purposes. These values were calculated in accordance with JESD51-7, and simulated on a specified JEDEC board. They do not represent the performance obtained in an actual application.
- 5) Measured on an MPS standard evaluation board (9cmx9cm), thick 2oz copper, 4-layer PCB.

ELECTRICAL CHARACTERISTICS

V_{IN} = 12V, V_{EN} = 2V, T_J = -40°C to +125°C⁽⁶⁾, unless otherwise noted, typical values are at T_J = 25°C.

| Parameter | Symbol | Condition | Min | Typ | Max | Units |
|---|------------------------------|--|-------|------|-------|-------|
| V _{IN} under-voltage lockout (UVLO) rising threshold | V _{IN_UVLO_RISING} | | 2.8 | 3 | 3.2 | V |
| V _{IN} UVLO falling threshold | V _{IN_UVLO_FALLING} | | 2.5 | 2.7 | 2.9 | V |
| V _{IN} UVLO hysteresis | V _{IN_UVLO_HYS} | | | 280 | | mV |
| VCC voltage | V _{CC} | I _{VCC} = 0A | 4.6 | 4.9 | 5.2 | V |
| VCC regulation | | I _{VCC} = 30mA | | 1 | 4 | % |
| VCC current limit | I _{LIMIT_VCC} | V _{CC} = 4V | 100 | | | mA |
| Quiescent current during sleep mode | I _{SLEEP} | V _{FB} = 0.85V, sleep mode, no load | | 18 | 26 | μA |
| Quiescent current | I _q | MODE is low, advanced asynchronous modulation (AAM) mode, no load, switching, R _{FB_PU} = 1MΩ, R _{FB_PD} = 324kΩ | | 20 | | μA |
| | | MODE is high, forced continuous conduction mode (FCCM), no load, switching, f _{SW} = 2MHz | | 40 | | mA |
| | | MODE is high, FCCM, no load, switching, f _{SW} = 470kHz | | 9.5 | | mA |
| Shutdown current | I _{SD} | V _{EN} = 0V | | 1.7 | 3.5 | μA |
| Feedback (FB) voltage | V _{FB} | V _{IN} = 3.3V to 45V, T _J = 25°C | 807 | 815 | 823 | mV |
| | | V _{IN} = 3.3V to 45V | 799 | 815 | 831 | mV |
| FB current | I _{FB} | V _{FB} = 0.85V | -50 | 0 | +50 | nA |
| Switching frequency | f _{SW} | R _{FREQ} = 62kΩ | 420 | 470 | 520 | kHz |
| | | R _{FREQ} = 26.1kΩ | 820 | 1000 | 1180 | |
| Minimum on time ⁽⁷⁾ | t _{ON_MIN} | | | 100 | | ns |
| Minimum off time ⁽⁷⁾ | t _{OFF_MIN} | | | 80 | | ns |
| SYNCIN voltage rising threshold | V _{SYNC_RISING} | | 1.8 | | | V |
| SYNCIN voltage falling threshold | V _{SYNC_FALLING} | | | | 0.4 | V |
| SYNCIN clock range | f _{SYNC} | External clock | 350 | | 1000 | kHz |
| SYNCO high voltage | V _{SYNCO_HIGH} | I _{SYNCO} = -1mA | 3.3 | 4.5 | | V |
| SYNCO low voltage | V _{SYNCO_LOW} | I _{SYNCO} = 1mA | | | 0.4 | V |
| SYNCO phase shift | | Tested under SYNCIN | | 180 | | deg |
| High-side MOSFET (HS-FET) peak current limit | I _{LIMIT_PEAK} | 30% duty cycle | 10 | 13 | 16 | A |
| Low-side MOSFET (LS-FET) valley current limit | I _{LIMIT_VALLEY} | | 8 | 10 | 12 | A |
| Zero-current detection (ZCD) current | I _{ZCD} | AAM mode | -0.15 | 0.1 | +0.35 | A |
| LS-FET reverse current limit | I _{LIMIT_REVERSE} | FCCM | 2 | 4.5 | 7 | A |
| Switch leakage current | I _{SW_LKG} | | | 0.01 | 1 | μA |
| HS-FET on resistance | R _{DS(ON)_HS} | V _{BST} - V _{SW} = 5V | | 48 | 80 | mΩ |
| LS-FET on resistance | R _{DS(ON)_LS} | V _{CC} = 5V | | 20 | 40 | mΩ |
| Soft-start current | I _{SS} | V _{SS} = 0V | 8 | 13 | 19 | μA |
| EN rising threshold | V _{EN_RISING} | | 0.8 | 1 | 1.2 | V |
| EN falling threshold | V _{EN_FALLING} | | 0.65 | 0.85 | 1.05 | V |

ELECTRICAL CHARACTERISTICS (continued)
V_{IN} = 12V, V_{EN} = 2V, T_J = -40°C to +125°C ⁽⁶⁾, unless otherwise noted, typical values are at T_J = 25°C.

| Parameter | Symbol | Condition | Min | Typ | Max | Units |
|--|-------------------------------|---|-------|-------|-------|-----------------------|
| MODE rising threshold | V _{MODE_RISING} | | 1.8 | | | V |
| MODE falling threshold | V _{MODE_FALLING} | | | | 0.4 | V |
| PG rising threshold | V _{PG_RISING} | V _{FB} rising, V _{FB} / V _{REF} | 92 | 95 | 98 | % of V _{REF} |
| | | V _{FB} falling, V _{FB} / V _{REF} | 102 | 105 | 108 | |
| PG falling threshold | V _{PG_FALLING} | V _{FB} falling, V _{FB} / V _{REF} | 90.5 | 93.5 | 96.5 | |
| | | V _{FB} rising, V _{FB} / V _{REF} | 103.5 | 106.5 | 109.5 | |
| PG output voltage low | V _{PG_LOW} | I _{SINK} = 1mA | | 0.1 | 0.3 | V |
| PG rising delay | t _{PG_DELAY_RISING} | | | 35 | | μs |
| PG falling delay | t _{PG_DELAY_FALLING} | | | 35 | | μs |
| Thermal shutdown ⁽⁷⁾ | T _{SD} | | | 170 | | °C |
| Thermal shutdown hysteresis ⁽⁷⁾ | T _{SD_HYS} | | | 20 | | °C |

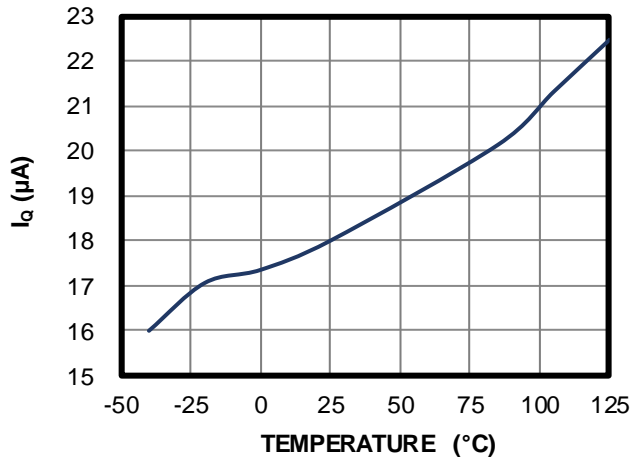
Notes:

- 6) Guaranteed by over-temperature correlation. Not tested in production.
 7) Derived from bench characterization. Not tested in production.

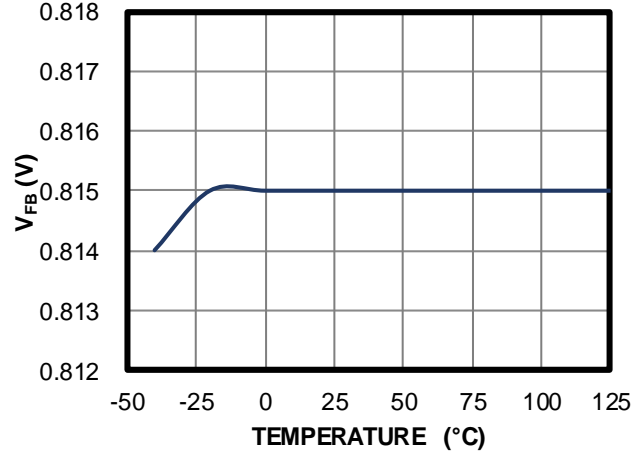
TYPICAL CHARACTERISTICS

$V_{IN} = 12V$, $T_J = -40^{\circ}C$ to $+125^{\circ}C$, unless otherwise noted.

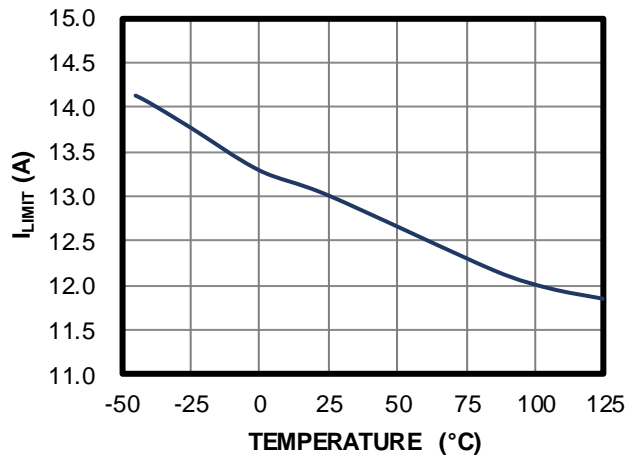
Quiescent Current vs. Temperature



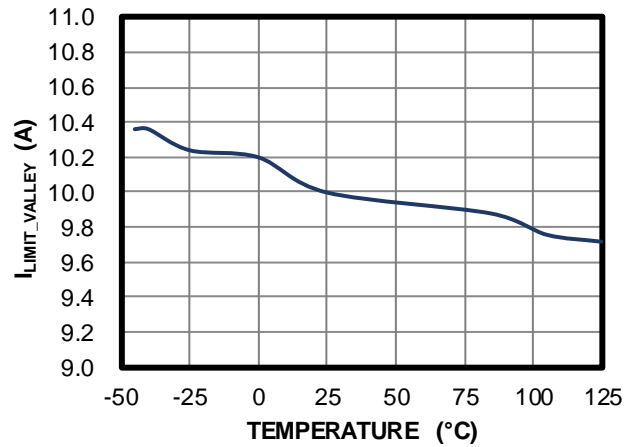
Feedback Voltage vs. Temperature



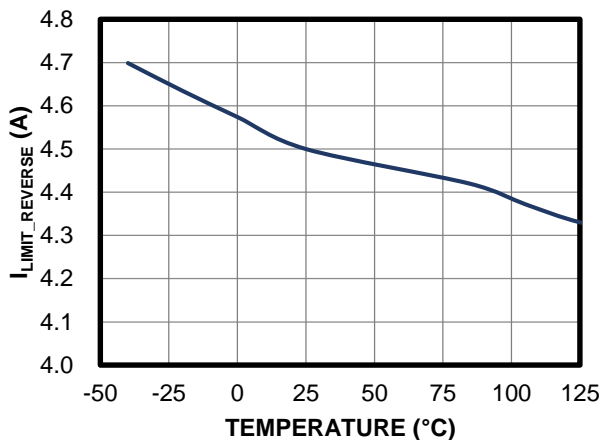
Current Limit vs. Temperature



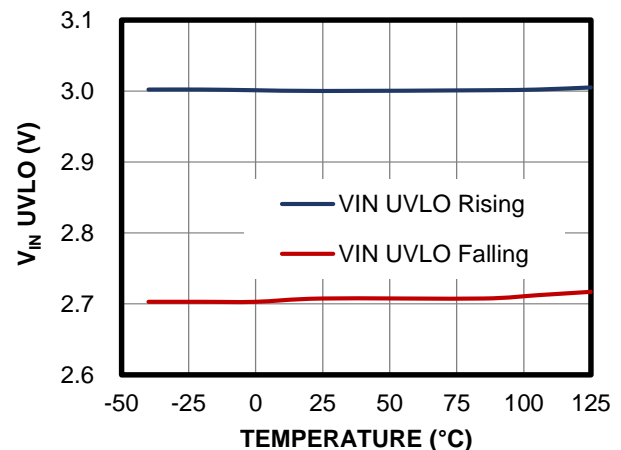
Valley Current Limit vs. Temperature



Reverse Current Limit vs. Temperature

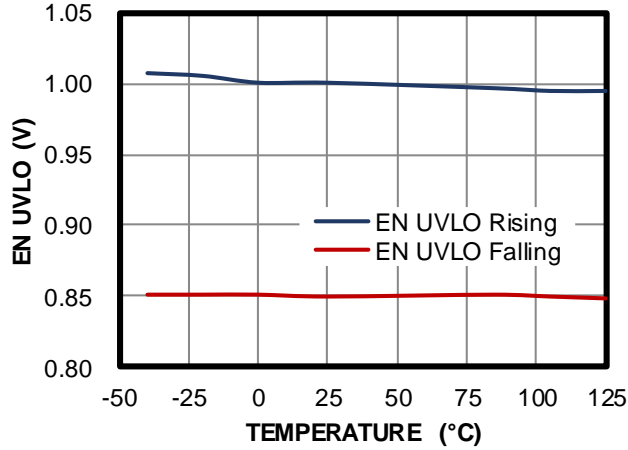
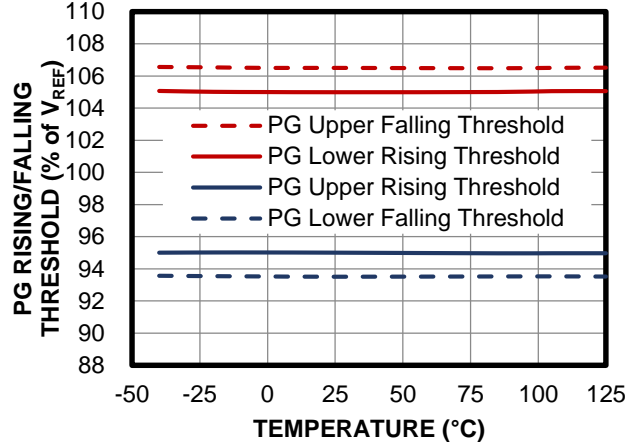
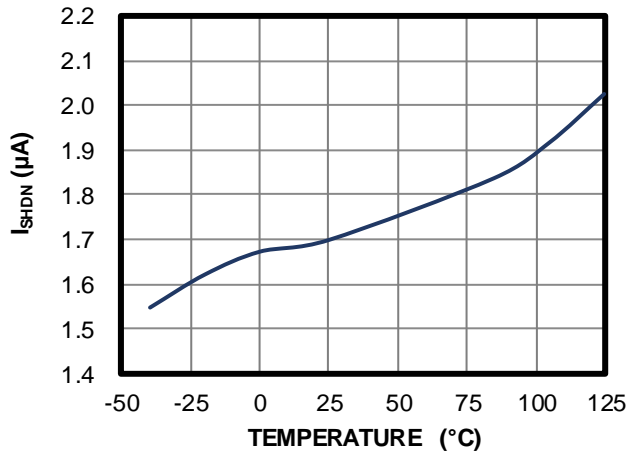
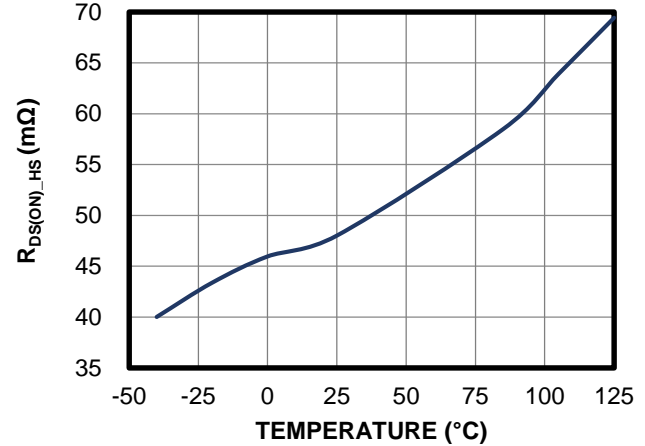
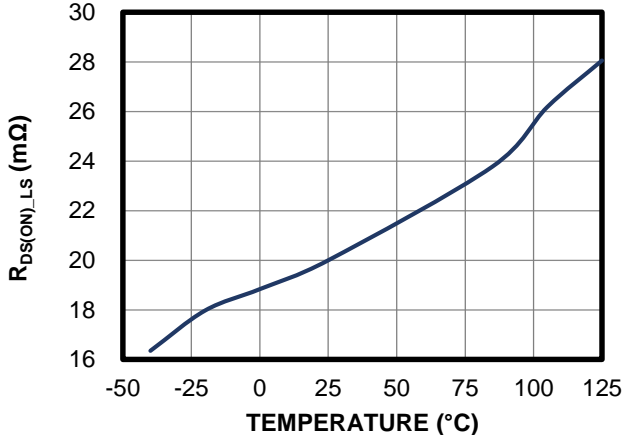
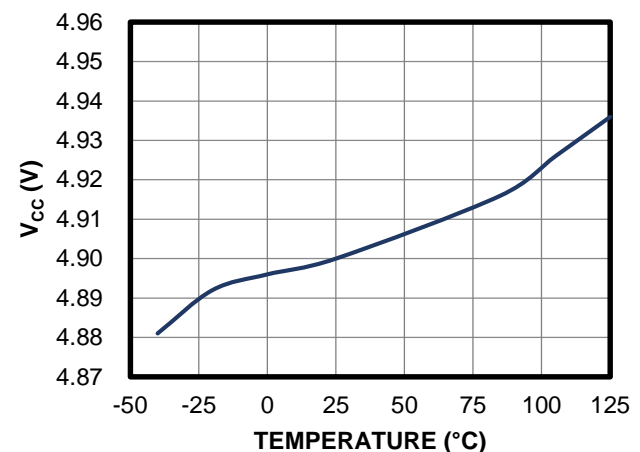


V_{IN} UVLO Threshold vs. Temperature



TYPICAL CHARACTERISTICS (continued)

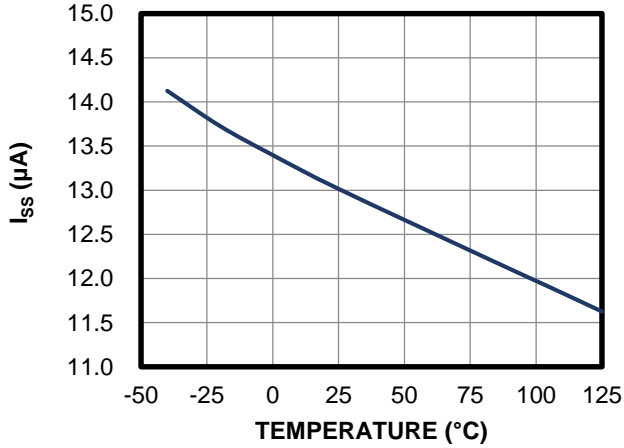
 V_{IN} = 12V, T_J = -40°C to +125°C, unless otherwise noted.

EN UVLO Threshold vs. Temperature

PG Threshold vs. Temperature

Shutdown Current vs. Temperature

HS-FET On Resistance vs. Temperature

LS-FET On Resistance vs. Temperature

V_{CC} vs. Temperature


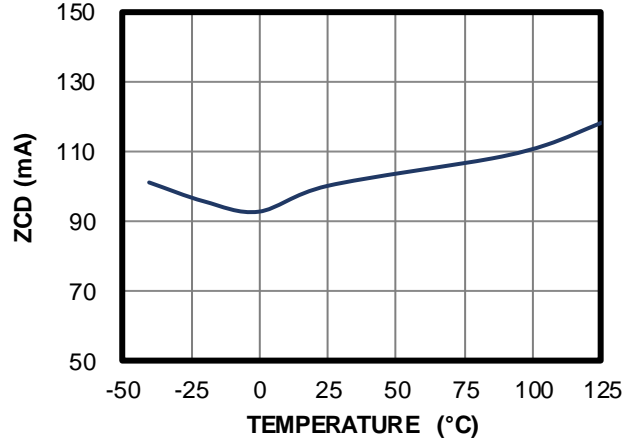
TYPICAL CHARACTERISTICS *(continued)*

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Soft-Start Current vs. Temperature

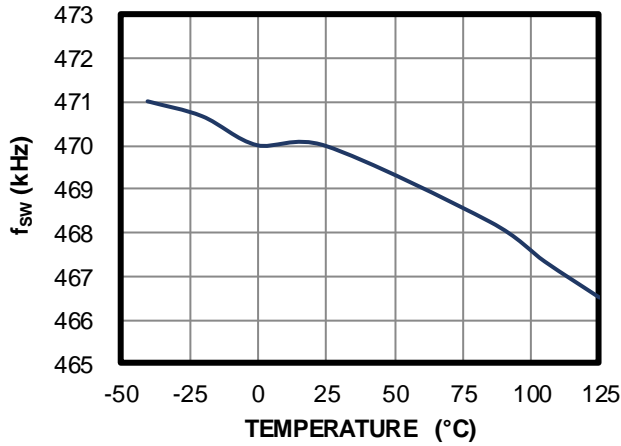


Zero-Current Detection vs. Temperature



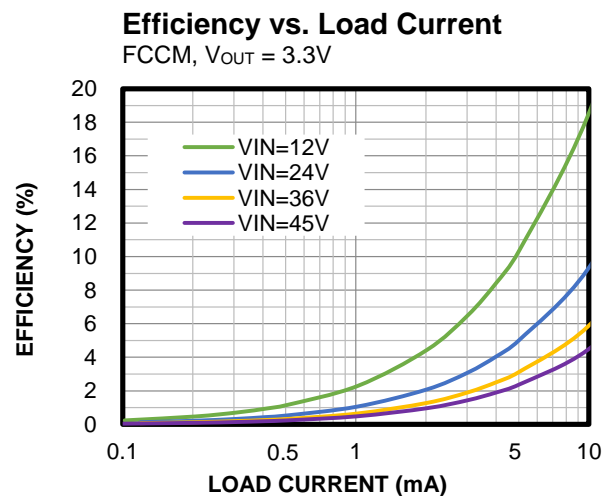
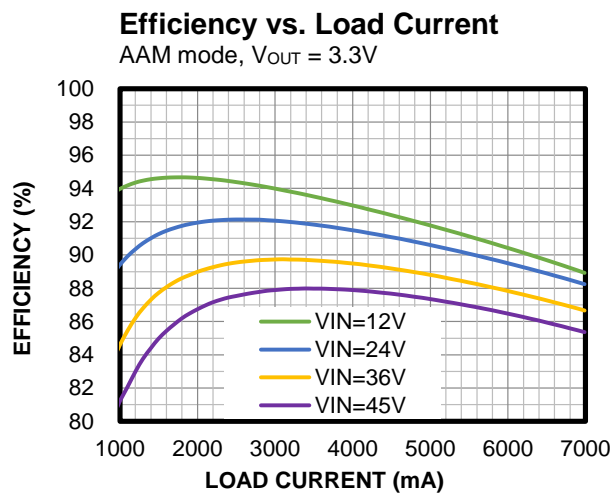
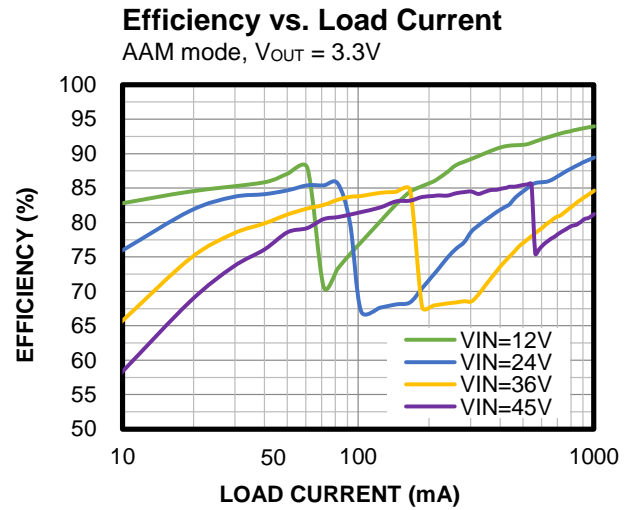
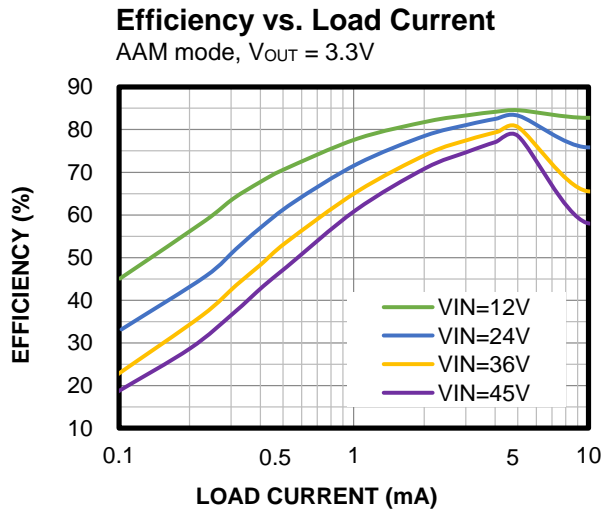
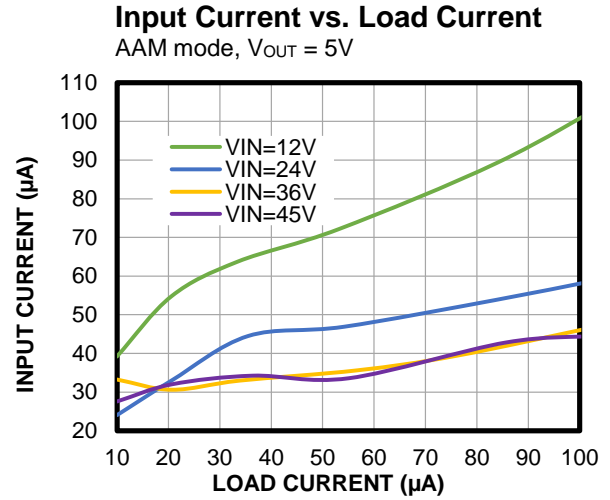
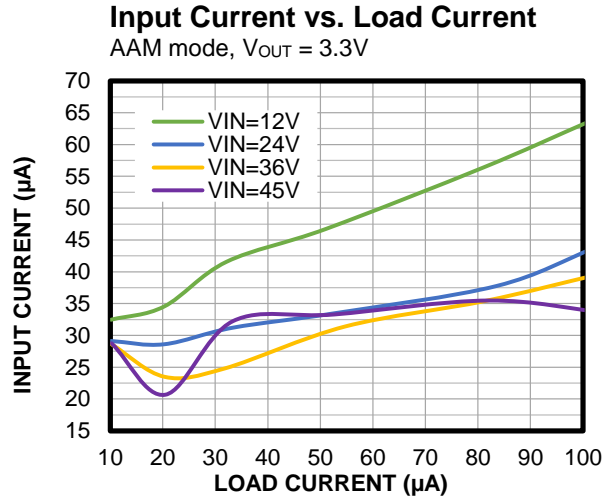
f_{sw} vs. Temperature

R_{FREQ} = 62kΩ



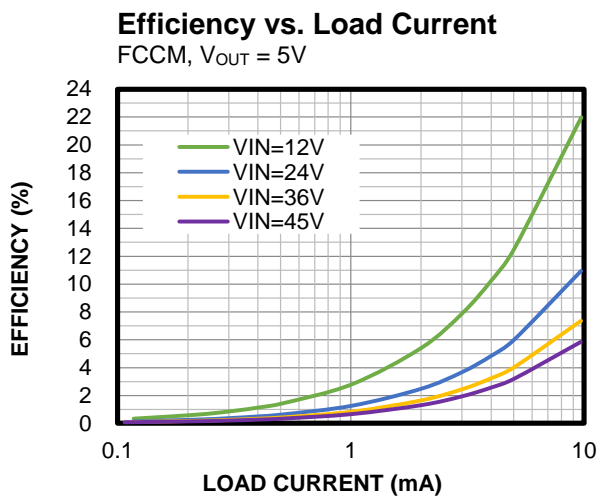
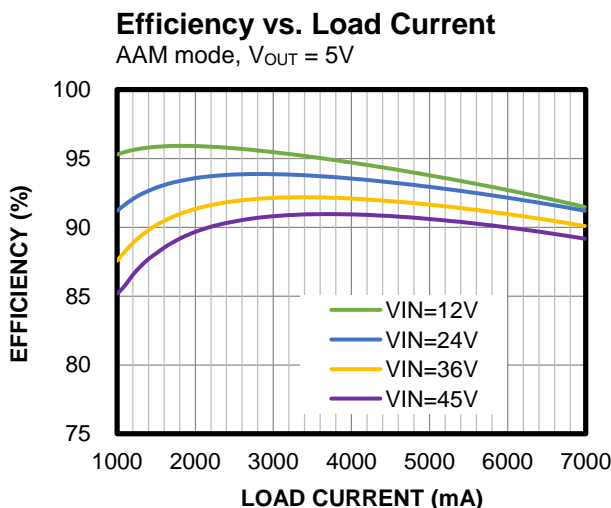
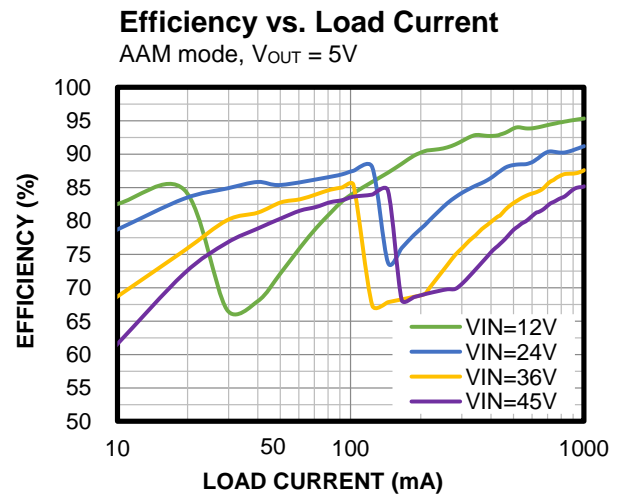
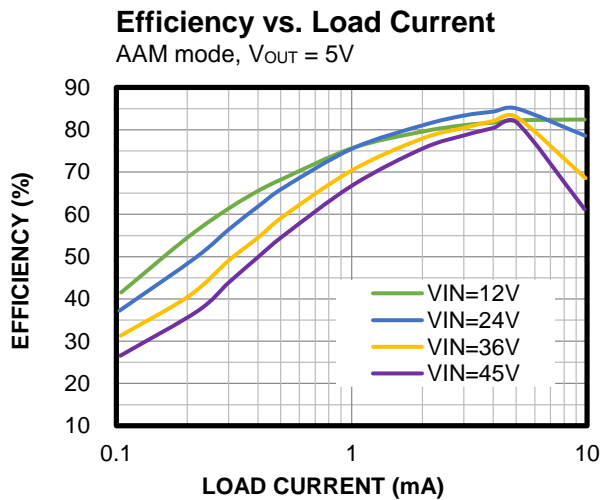
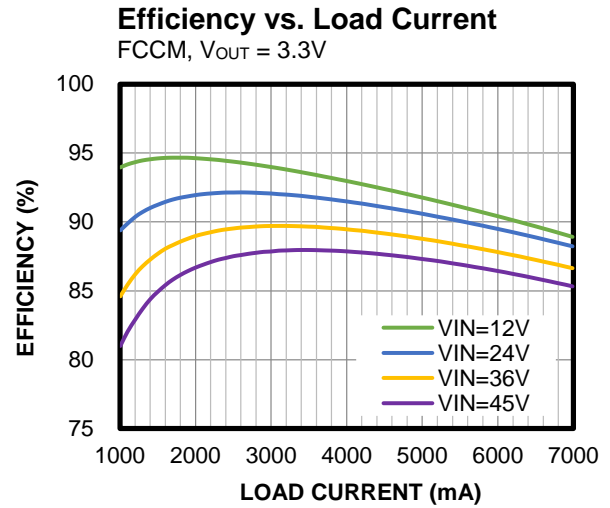
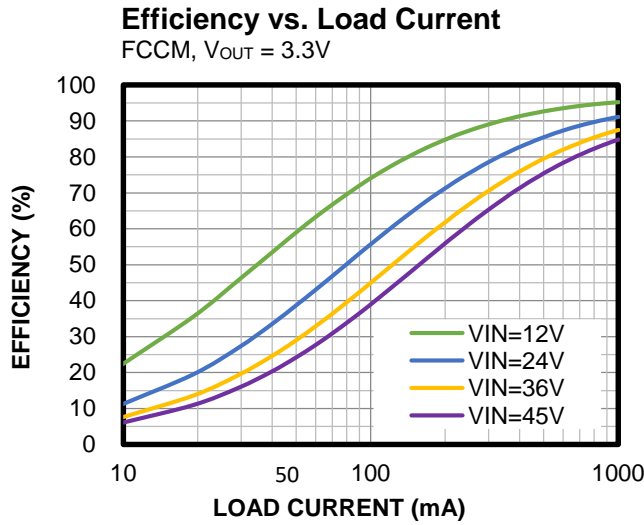
TYPICAL PERFORMANCE CHARACTERISTICS

V_{IN} = 12V, V_{OUT} = 3.3V, L = 4.7μH⁽⁸⁾, f_{sw} = 470kHz, AAM mode, T_A = 25°C, unless otherwise noted.



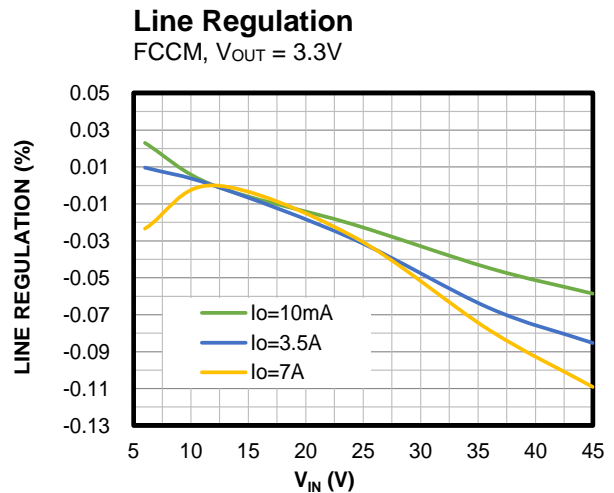
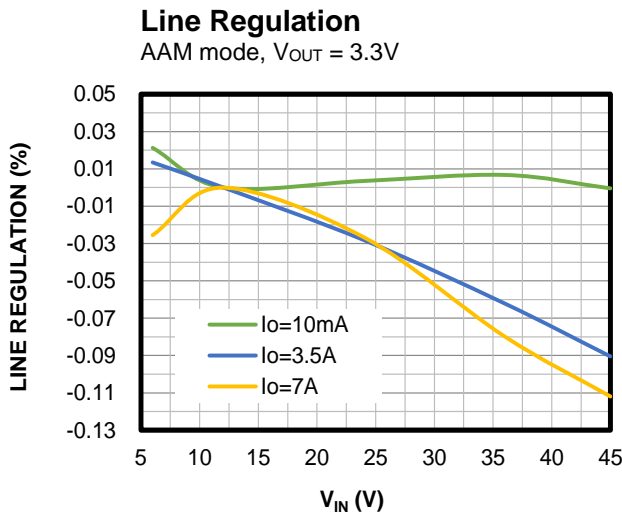
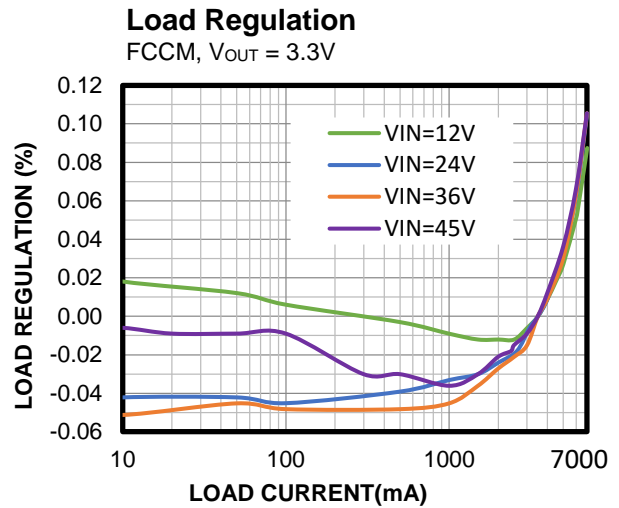
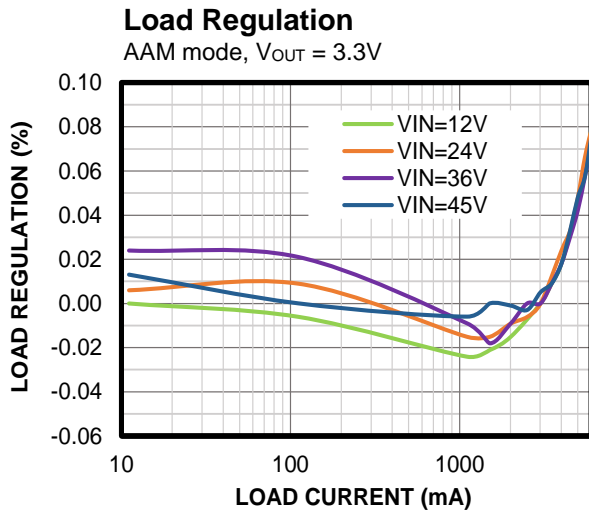
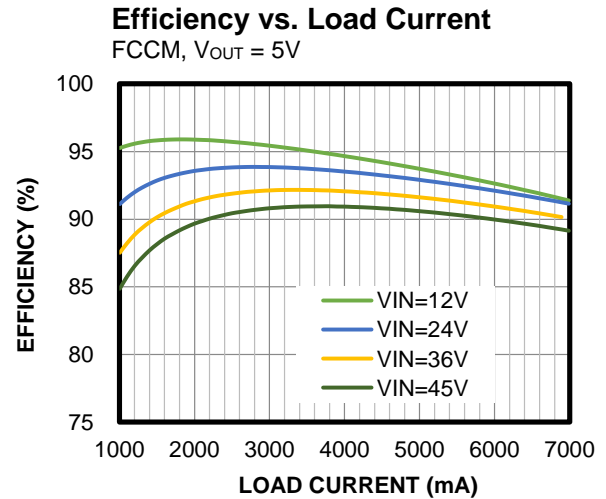
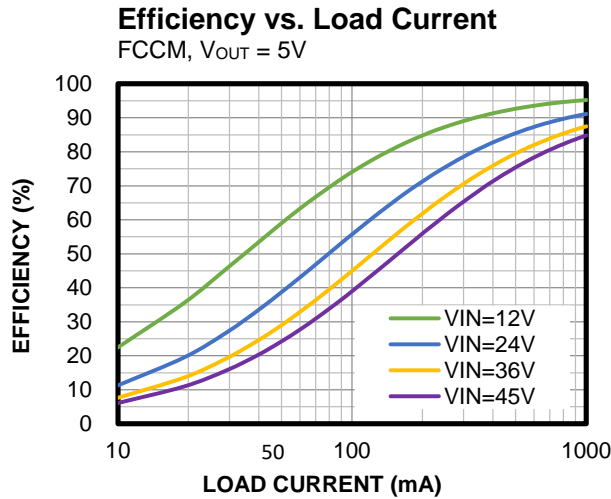
TYPICAL PERFORMANCE CHARACTERISTICS (continued)

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TYPICAL PERFORMANCE CHARACTERISTICS *(continued)*

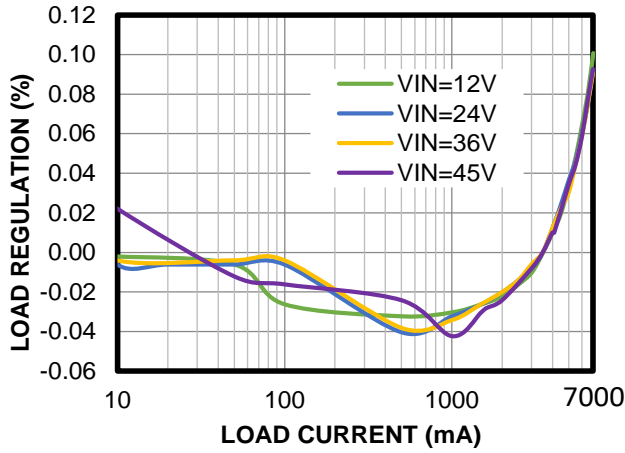
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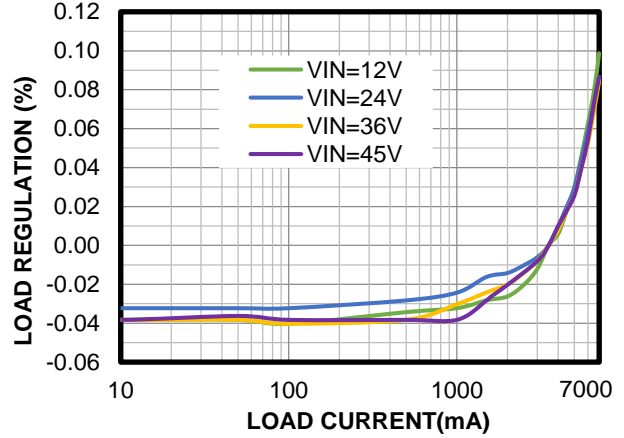


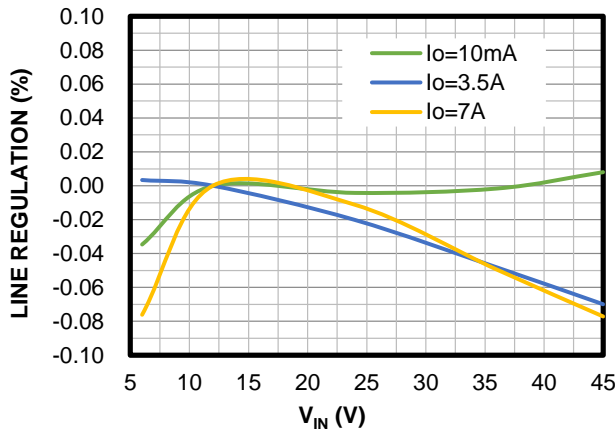
TYPICAL PERFORMANCE CHARACTERISTICS (continued)

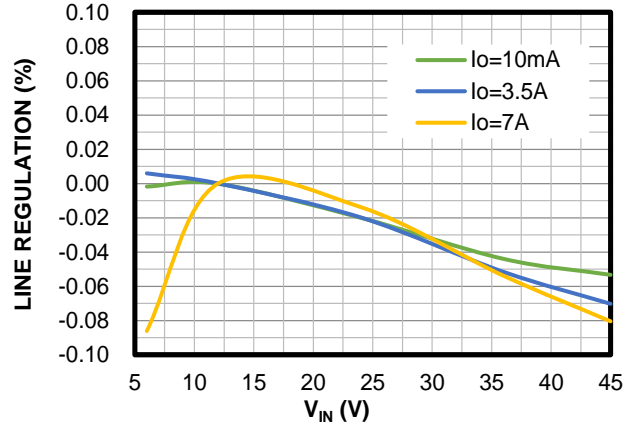
 V_{IN} = 12V, V_{OUT} = 3.3V, L = 4.7μH⁽⁸⁾, f_{sw} = 470kHz, AAM mode, T_A = 25°C, unless otherwise noted.

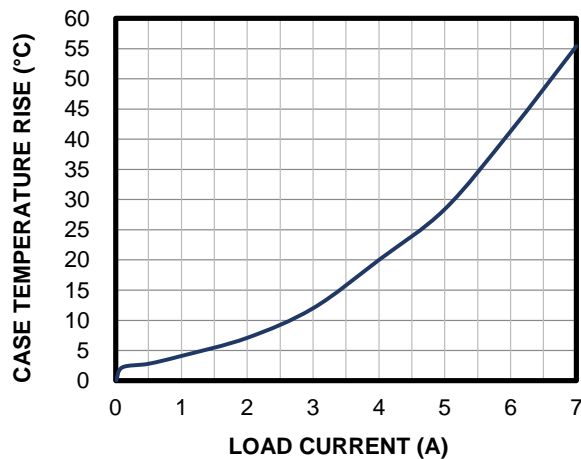
Load Regulation

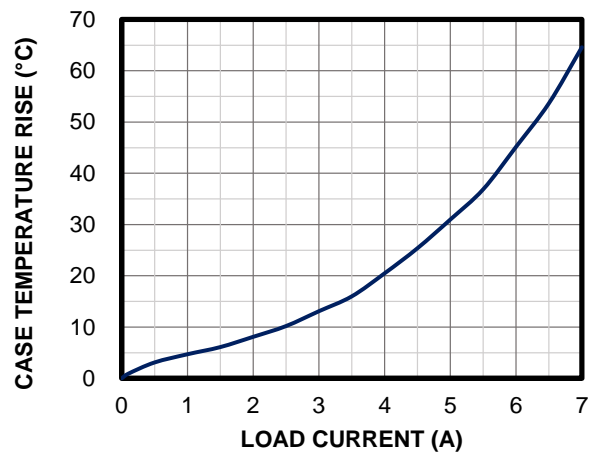
 AAM mode, V_{OUT} = 5V

Load Regulation

 FCCM, V_{OUT} = 5V

Line Regulation

 AAM mode, V_{OUT} = 5V

Line Regulation

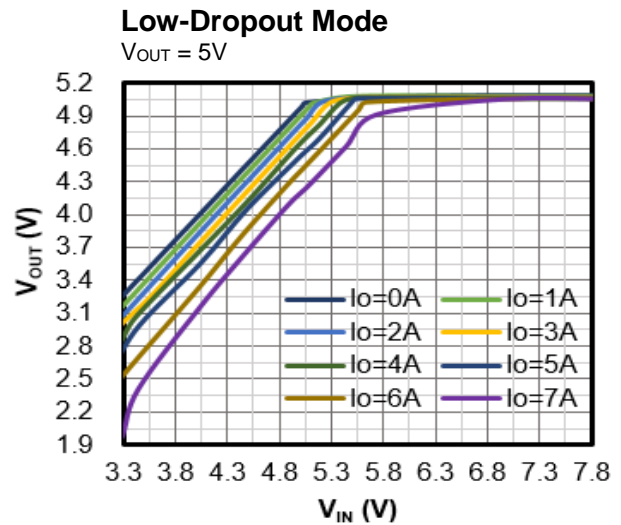
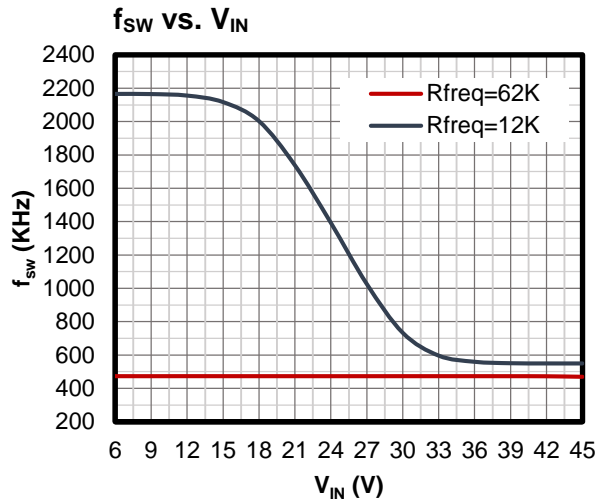
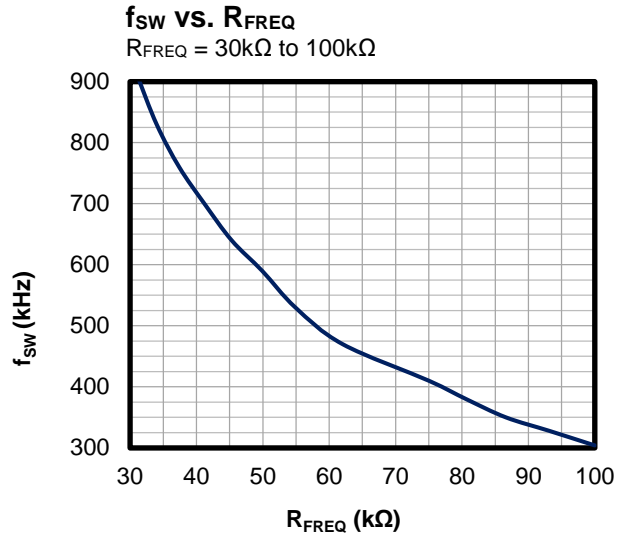
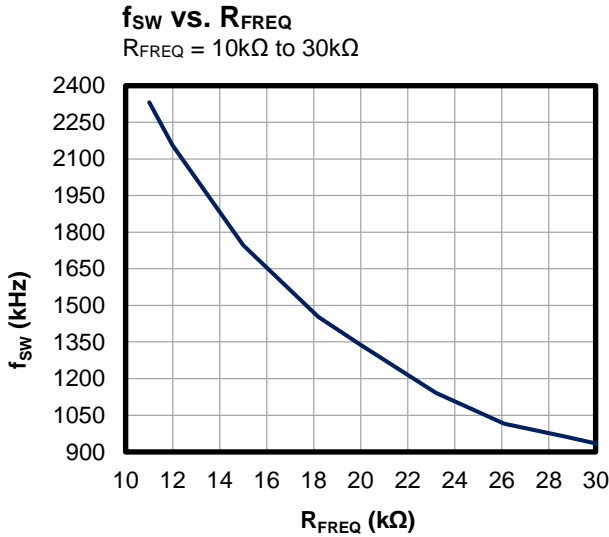
 FCCM, V_{OUT} = 5V

Case Temperature Rise

 V_{OUT} = 3.3V

Case Temperature Rise

 V_{OUT} = 5V


TYPICAL PERFORMANCE CHARACTERISTICS *(continued)*

V_{IN} = 12V, V_{OUT} = 3.3V, L = 4.7μH⁽⁸⁾, f_{sw} = 470kHz, AAM mode, T_A = 25°C, unless otherwise noted.

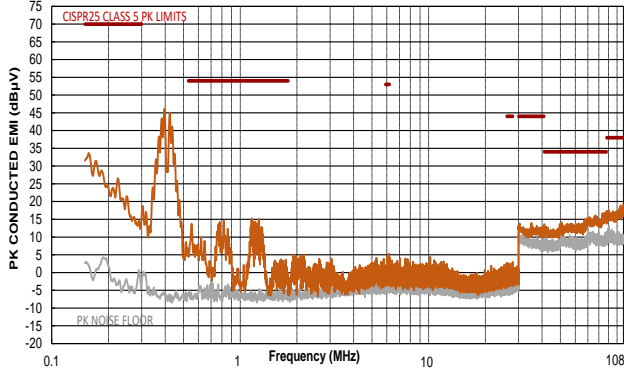


TYPICAL PERFORMANCE CHARACTERISTICS *(continued)*

V_{IN} = 12V, V_{OUT} = 5V, I_{OUT} = 7A, L = 4.7μH ⁽⁸⁾, f_{sw} = 410kHz, T_A = 25°C, unless otherwise noted. ⁽⁹⁾

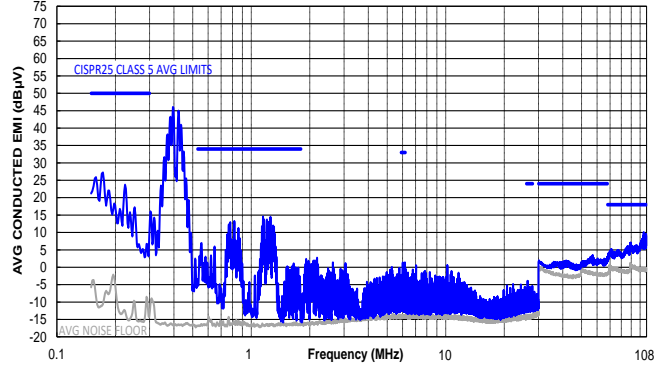
CISPR25 Class 5 Peak Conducted Emissions

150kHz to 108MHz



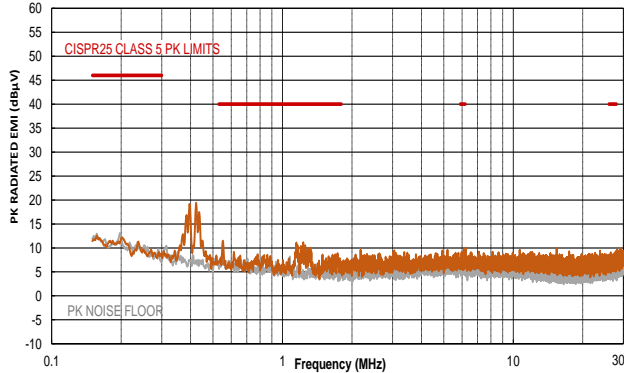
CISPR25 Class 5 Average Conducted Emissions

150kHz to 108MHz



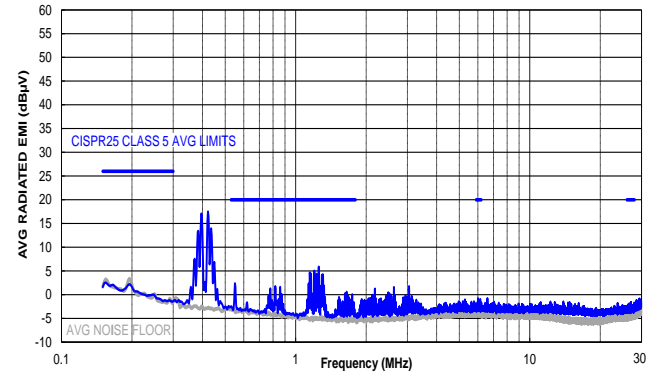
CISPR25 Class 5 Peak Radiated Emissions

150kHz to 30MHz



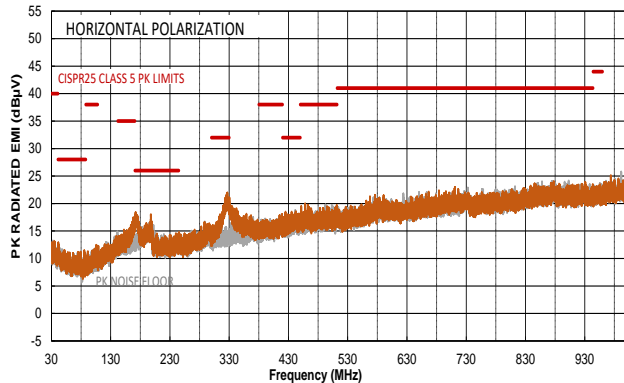
CISPR25 Class 5 Average Radiated Emissions

150kHz to 30MHz



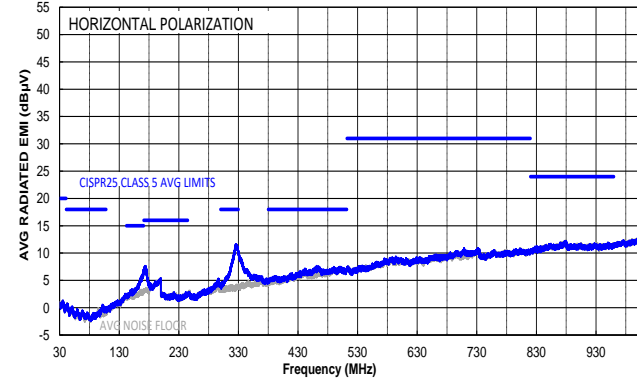
CISPR25 Class 5 Peak Radiated Emissions

Horizontal, 30MHz to 1GHz



CISPR25 Class 5 Average Radiated Emissions

Horizontal, 30MHz to 1GHz

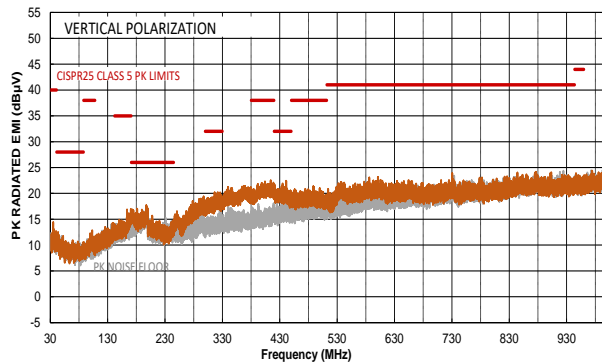


TYPICAL PERFORMANCE CHARACTERISTICS *(continued)*

V_{IN} = 12V, V_{OUT} = 5V, I_{OUT} = 7A, L = 4.7μH⁽⁸⁾, f_{SW} = 410kHz, T_A = 25°C, unless otherwise noted.⁽⁹⁾

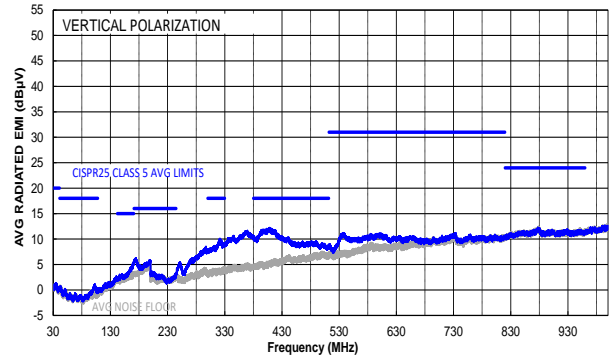
CISPR25 Class 5 Peak Radiated Emissions

Vertical, 30MHz to 1GHz



CISPR25 Class 5 Average Radiated Emissions

Vertical, 30MHz to 1GHz



Notes:

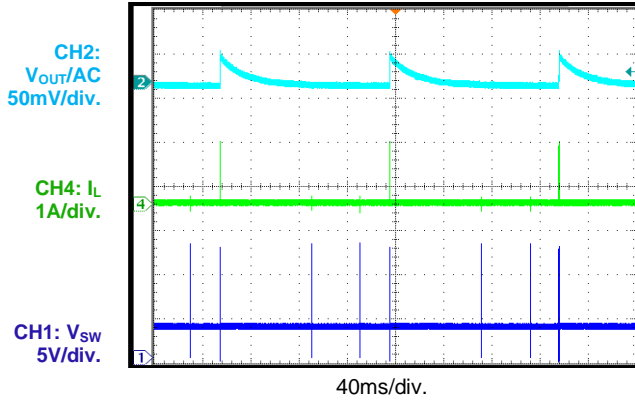
- 8) Inductor part number: XAL6060-472MEC; DCR = 15mΩ.
- 9) The EMC test results are based on the typical application circuit with EMI filters (see Figure 11 on page 35).

TYPICAL PERFORMANCE CHARACTERISTICS (continued)

$V_{IN} = 12V$, $V_{OUT} = 3.3V$, $L = 4.7\mu H$, $f_{sw} = 470kHz$, AAM mode, $T_A = 25^{\circ}C$, unless otherwise noted.

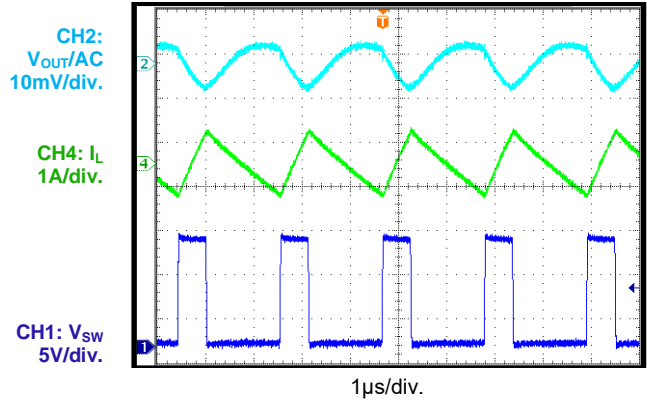
Steady State

$I_{OUT} = 0A$, AAM mode



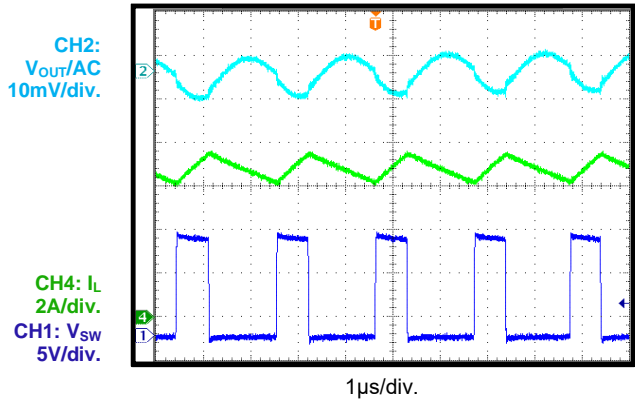
Steady State

$I_{OUT} = 0A$, FCCM



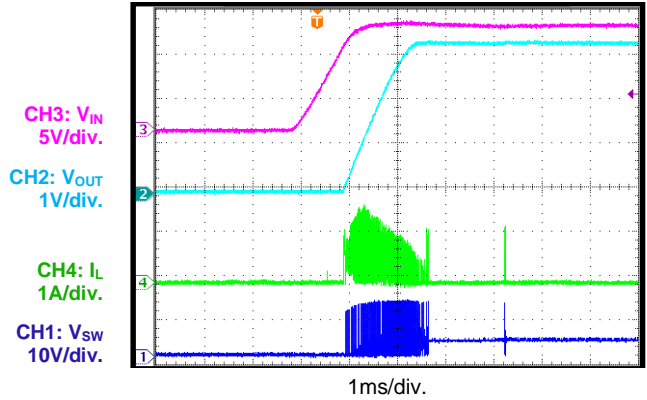
Steady State

$I_{OUT} = 7A$



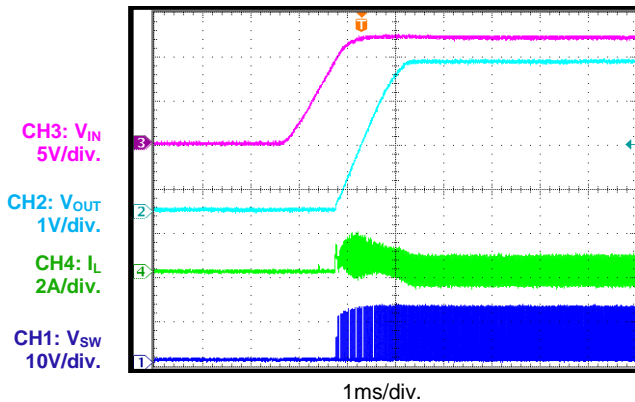
Start-Up through VIN

$I_{OUT} = 0A$, AAM mode



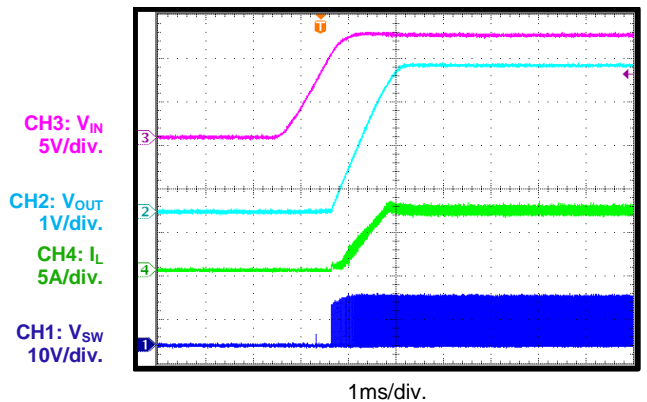
Start-Up through VIN

$I_{OUT} = 0A$, FCCM



Start-Up through VIN

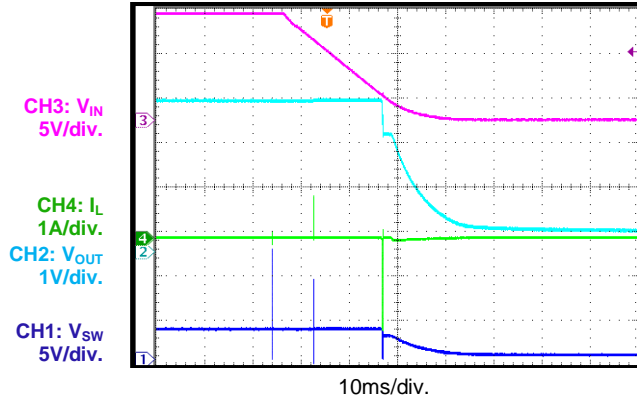
$I_{OUT} = 7A$

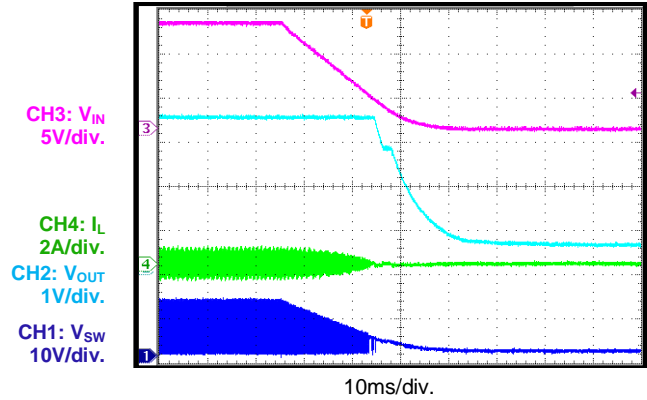


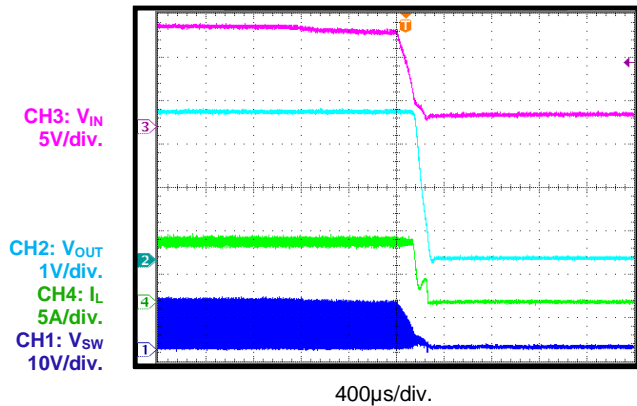
TYPICAL PERFORMANCE CHARACTERISTICS (continued)

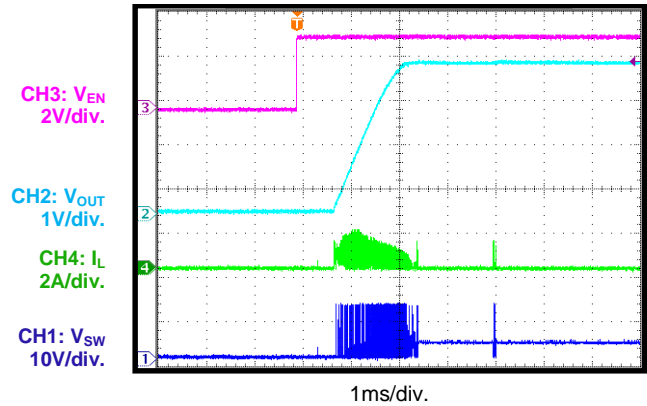
 V_{IN} = 12V, V_{OUT} = 3.3V, L = 4.7μH, f_{sw} = 470kHz, AAM mode, T_A = 25°C, unless otherwise noted.

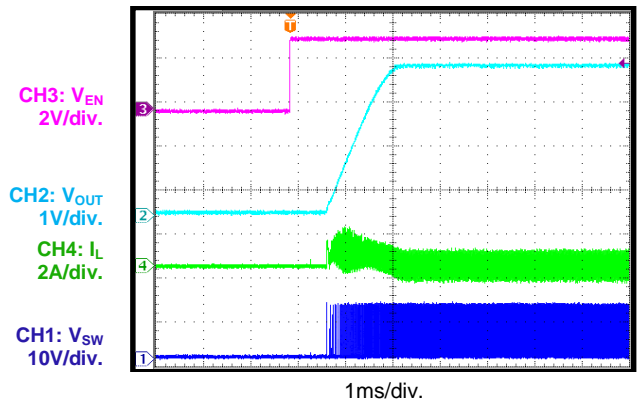
Shutdown through VIN

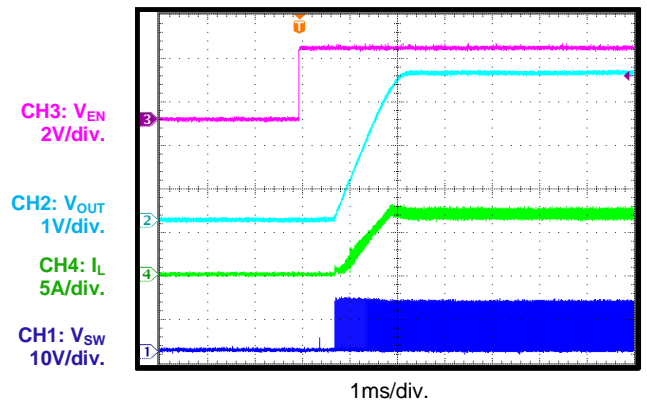
 I_{OUT} = 0A, AAM mode

Shutdown through VIN

 I_{OUT} = 0A, FCCM

Shutdown through VIN

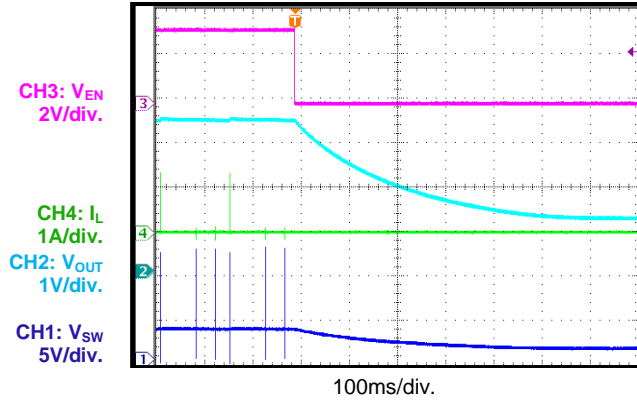
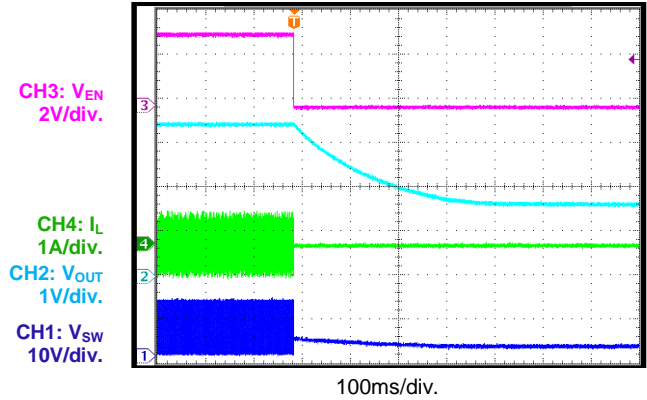
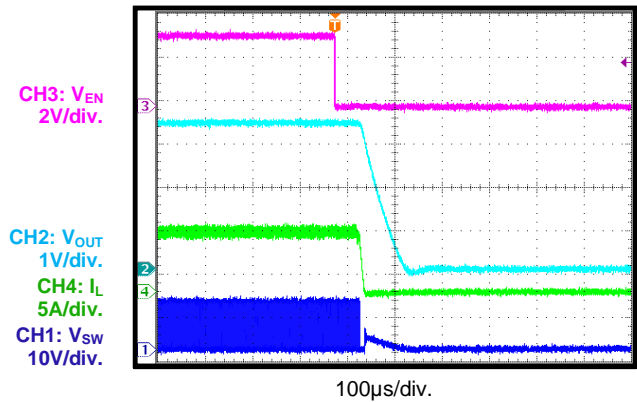
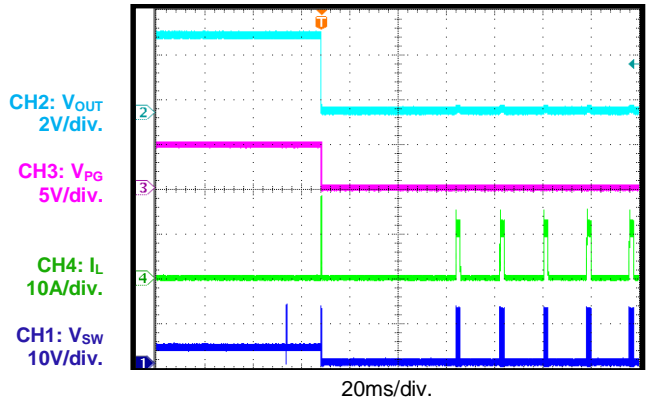
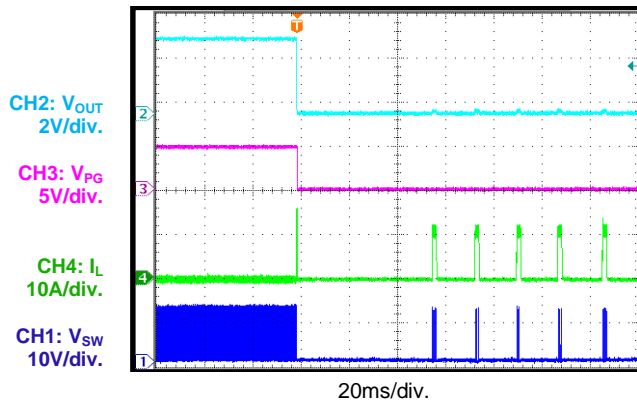
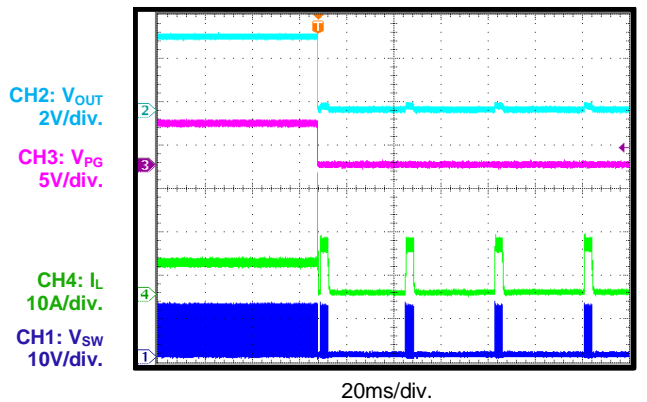
 I_{OUT} = 7A

Start-Up through EN

 I_{OUT} = 0A, AAM mode

Start-Up through EN

 I_{OUT} = 0A, FCCM

Start-Up through EN

 I_{OUT} = 7A


TYPICAL PERFORMANCE CHARACTERISTICS (continued)
 $V_{IN} = 12V$, $V_{OUT} = 3.3V$, $L = 4.7\mu H$, $f_{sw} = 470kHz$, AAM mode, $T_A = 25^{\circ}C$, unless otherwise noted.

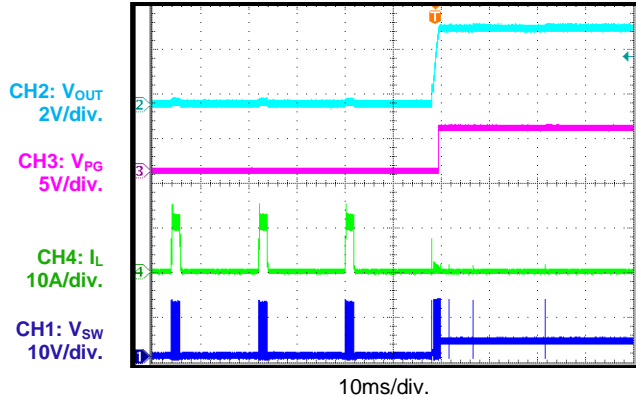
Shutdown through EN
 $I_{OUT} = 0A$, AAM mode

Shutdown through EN
 $I_{OUT} = 0A$, FCCM

Shutdown through EN
 $I_{OUT} = 7A$

SCP Entry
 $I_{OUT} = 0A$, AAM mode

SCP Entry
 $I_{OUT} = 0A$, FCCM

SCP Entry
 $I_{OUT} = 7A$


TYPICAL PERFORMANCE CHARACTERISTICS *(continued)*

V_{IN} = 12V, V_{OUT} = 3.3V, L = 4.7μH, f_{sw} = 470kHz, AAM mode, T_A = 25°C, unless otherwise noted.

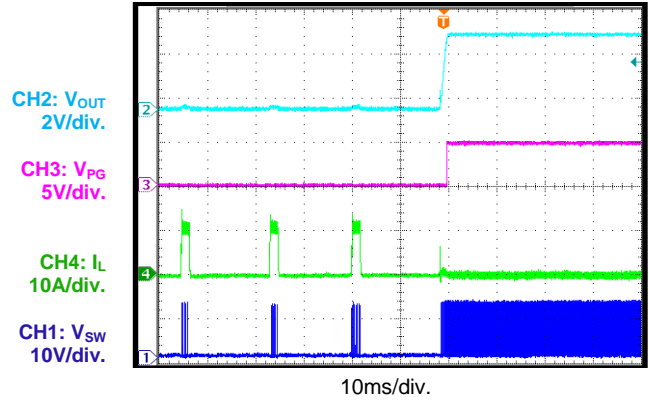
SCP Recovery

I_{OUT} = 0A, AAM mode



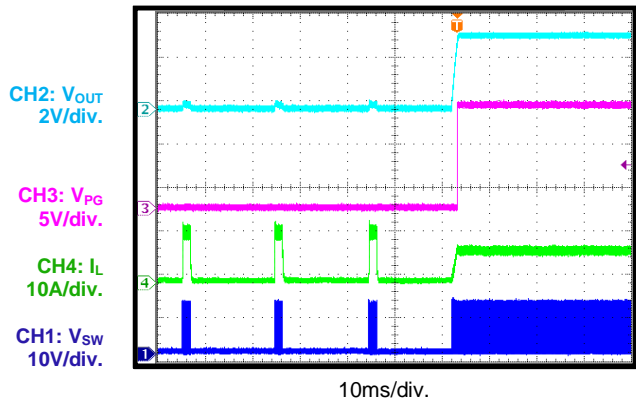
SCP Recovery

I_{OUT} = 0A, FCCM

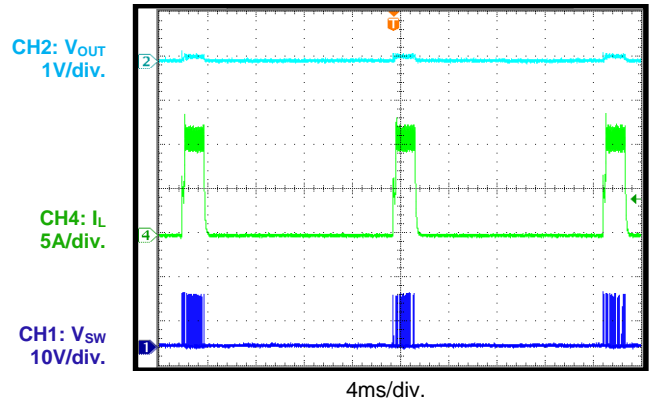


SCP Recovery

I_{OUT} = 7A

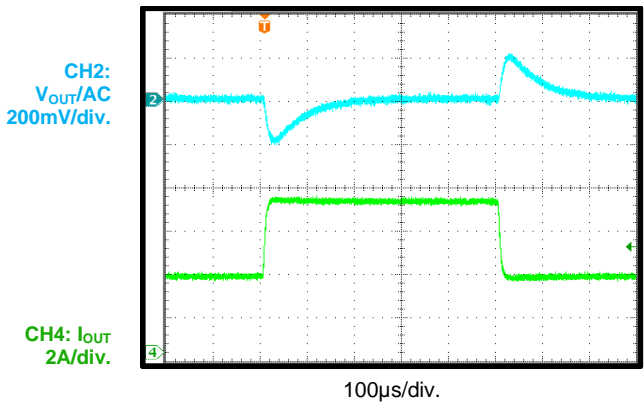


SCP Steady State



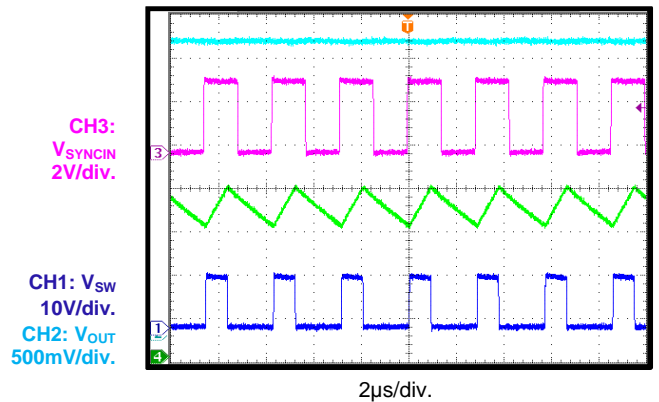
Load Transient

I_{OUT} = 3.5A to 7A, 1.6A/μs



SYNCIN Operation

I_{OUT} = 7A, f_{SYNC} = 350kHz

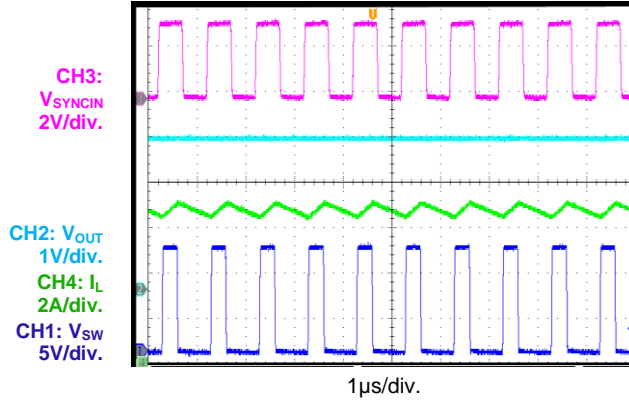


TYPICAL PERFORMANCE CHARACTERISTICS (continued)

V_{IN} = 12V, V_{OUT} = 3.3V, L = 4.7μH, f_{sw} = 470kHz, AAM mode, T_A = 25°C, unless otherwise noted.

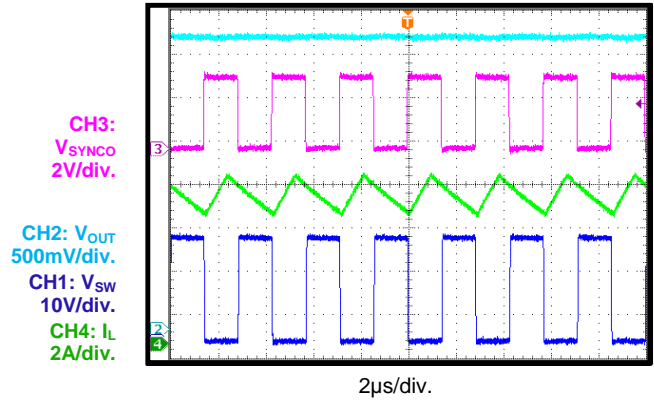
SYNCIN Operation

I_{OUT} = 7A, f_{SYNC} = 1000kHz



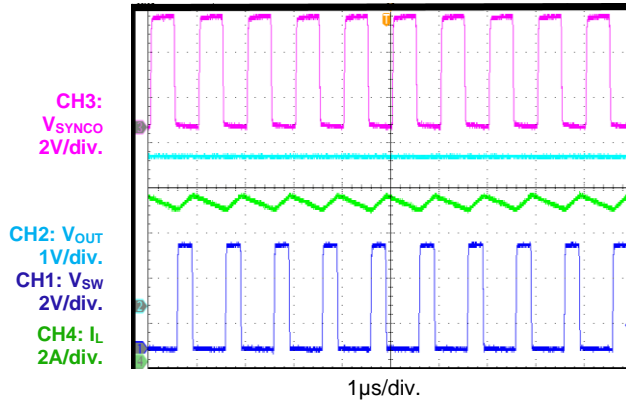
SYNCO Operation

I_{OUT} = 7A, f_{SYNC} = 350kHz



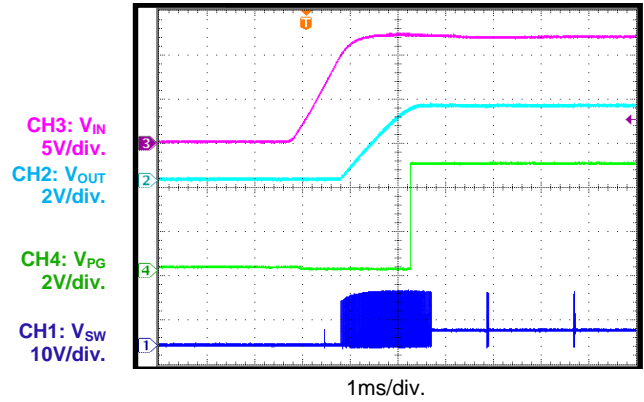
SYNCO Operation

I_{OUT} = 7A, f_{SYNC} = 1000kHz



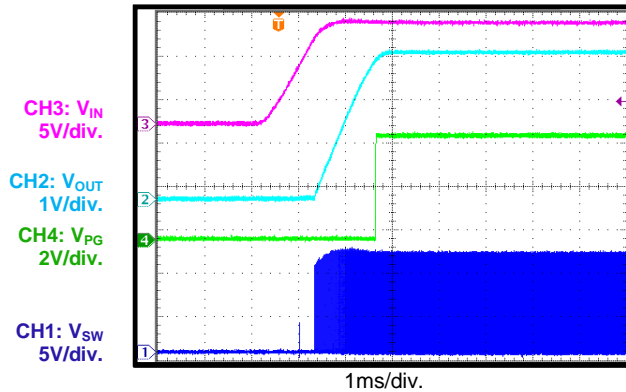
PG Start-Up through VIN

I_{OUT} = 0A



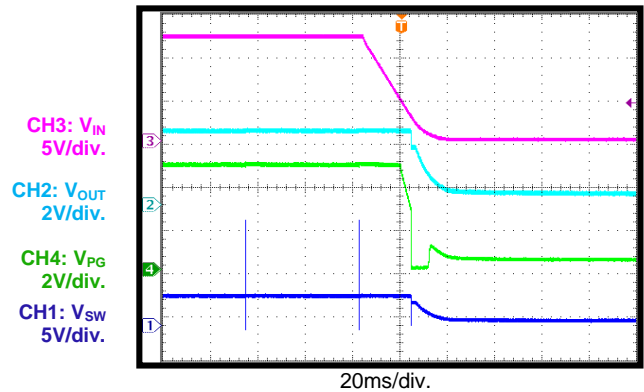
PG Start-Up through VIN

I_{OUT} = 7A



PG Shutdown through VIN

I_{OUT} = 0A

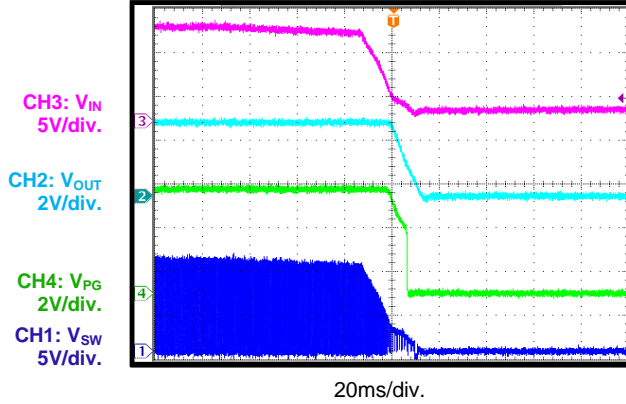


TYPICAL PERFORMANCE CHARACTERISTICS *(continued)*

V_{IN} = 12V, V_{OUT} = 3.3V, L = 4.7μH, f_{sw} = 470kHz, AAM mode, T_A = 25°C, unless otherwise noted.

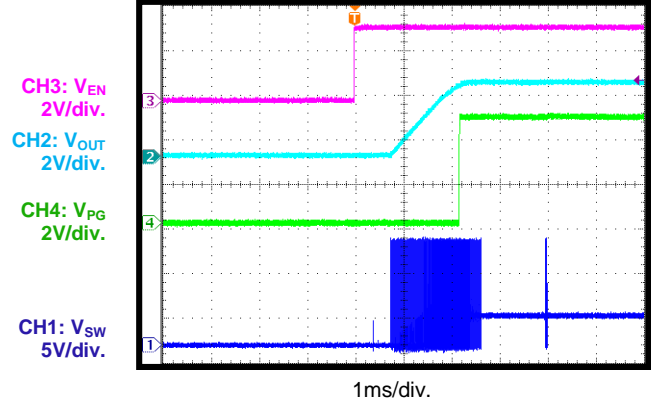
PG in Shutdown through VIN

I_{OUT} = 7A



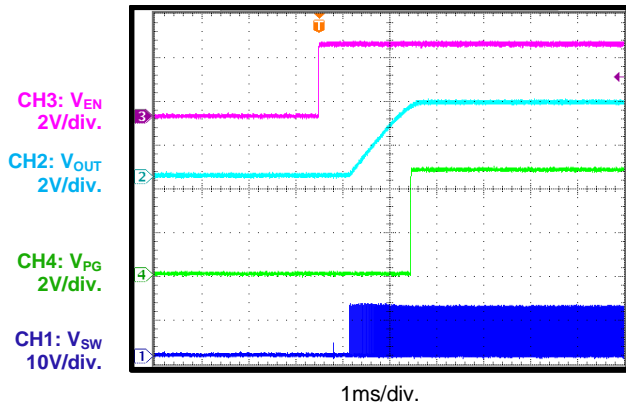
PG Start-Up through EN

I_{OUT} = 0A



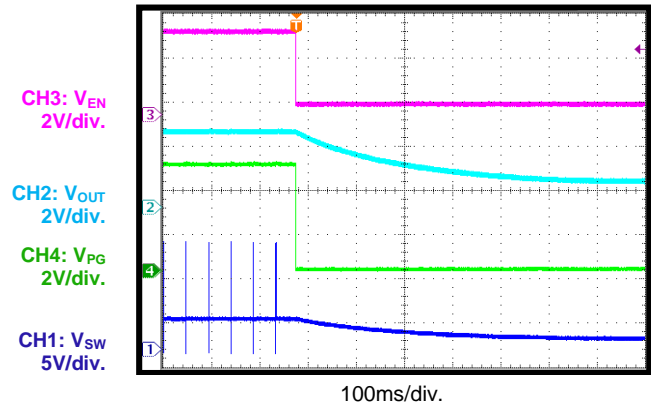
PG Start-Up through EN

I_{OUT} = 7A



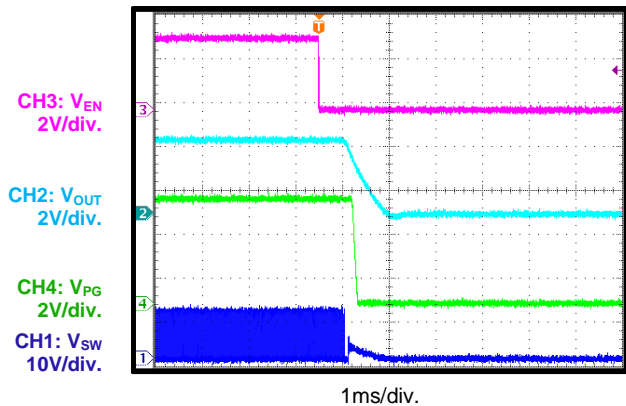
PG Shutdown through EN

I_{OUT} = 0A



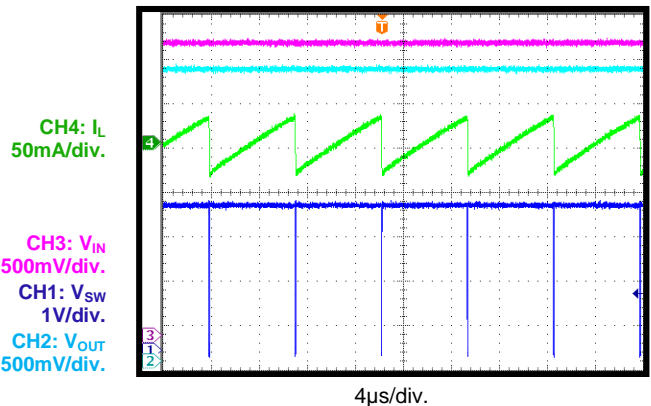
PG Shutdown through EN

I_{OUT} = 7A



Low-Dropout Mode

V_{IN} = 3.3V, V_{OUT} = 3.3V, I_{OUT} = 0A

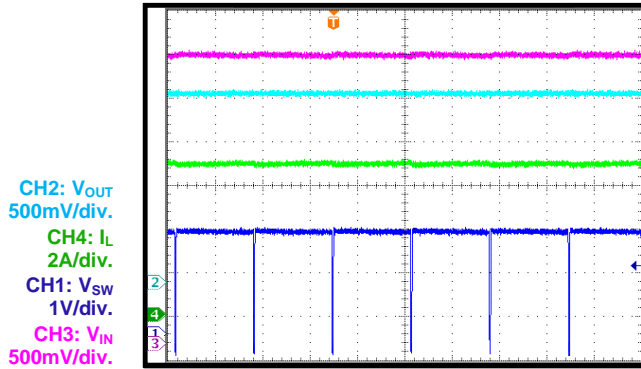


TYPICAL PERFORMANCE CHARACTERISTICS *(continued)*

V_{IN} = 12V, V_{OUT} = 3.3V, L = 4.7μH, f_{sw} = 470kHz, AAM mode, T_A = 25°C, unless otherwise noted.

Low-Dropout Mode

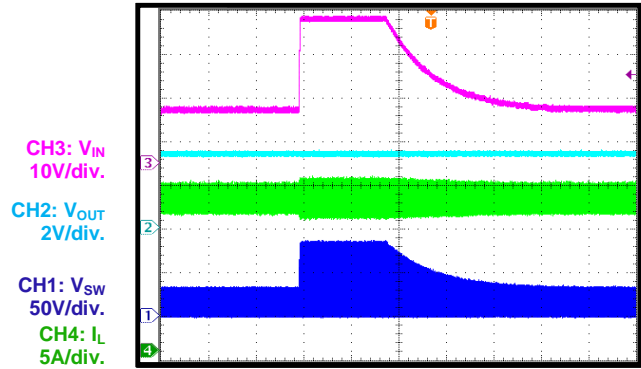
V_{IN} = 3.3V, V_{OUT} = 3.3V, I_{OUT} = 7A



4μs/div.

Load Dump

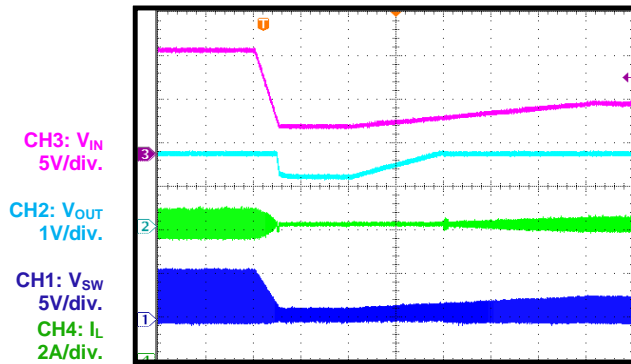
V_{IN} = 12V to 36V, I_{OUT} = 7A



100ms/div.

Cold Crank

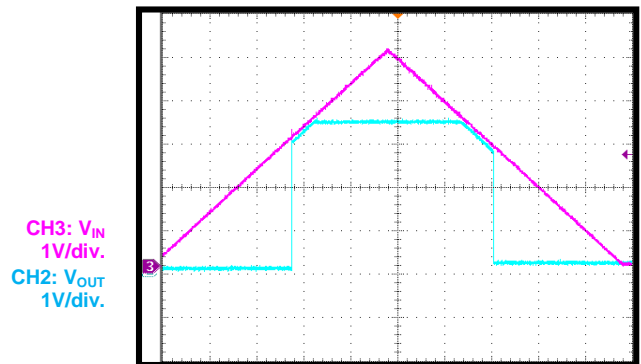
V_{IN} = 12V to 3.3V to 5V, I_{OUT} = 7A



4ms/div.

V_{IN} Ramps Up and Down

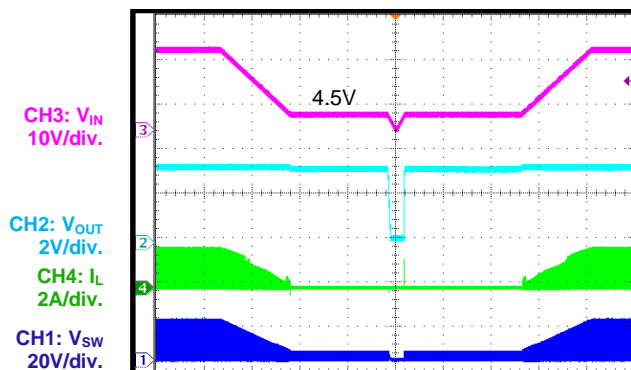
I_{OUT} = 0.1A



1s/div.

V_{IN} Ramps Down and Up

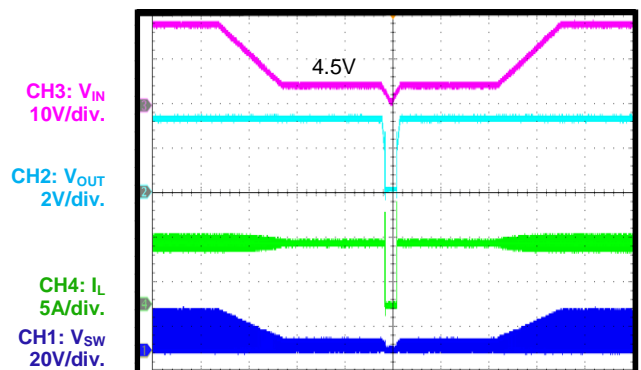
I_{OUT} = 1mA



10s/div.

V_{IN} Ramps Down and Up

I_{OUT} = 7A



10s/div.

FUNCTIONAL BLOCK DIAGRAM

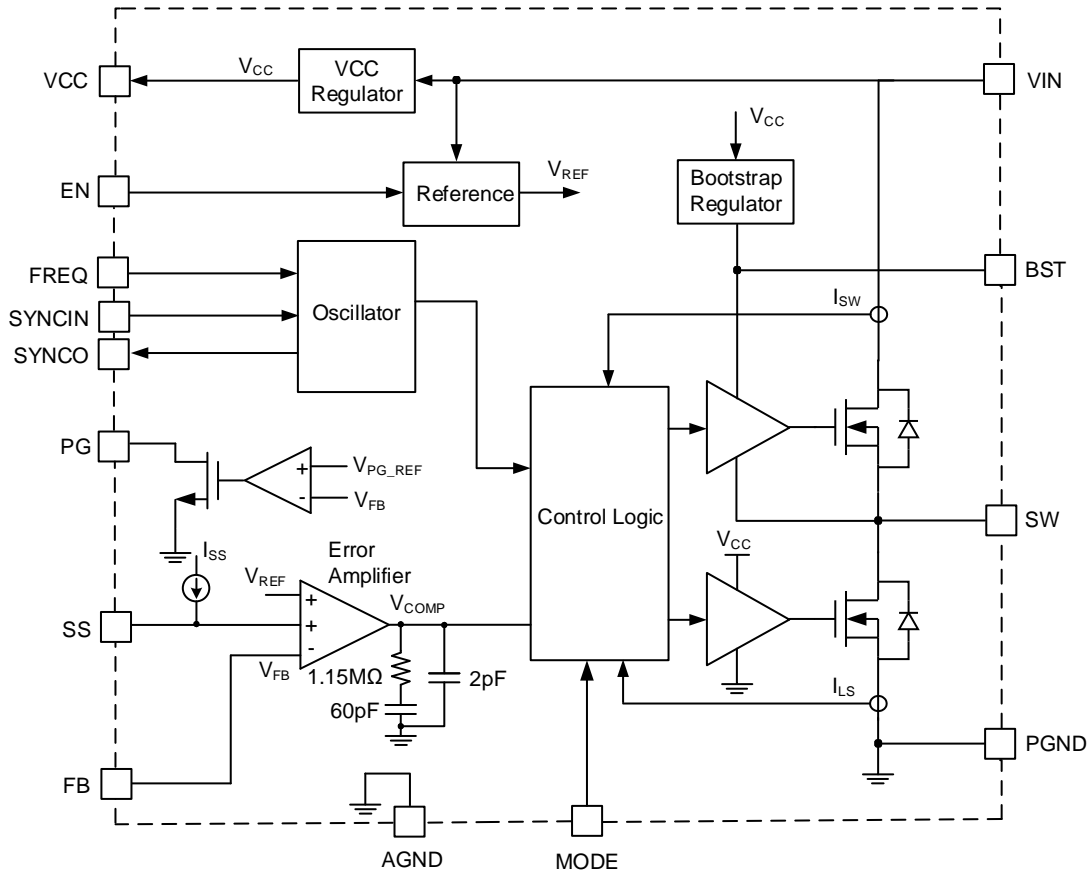


Figure 1: Functional Block Diagram

TIMING SEQUENCE

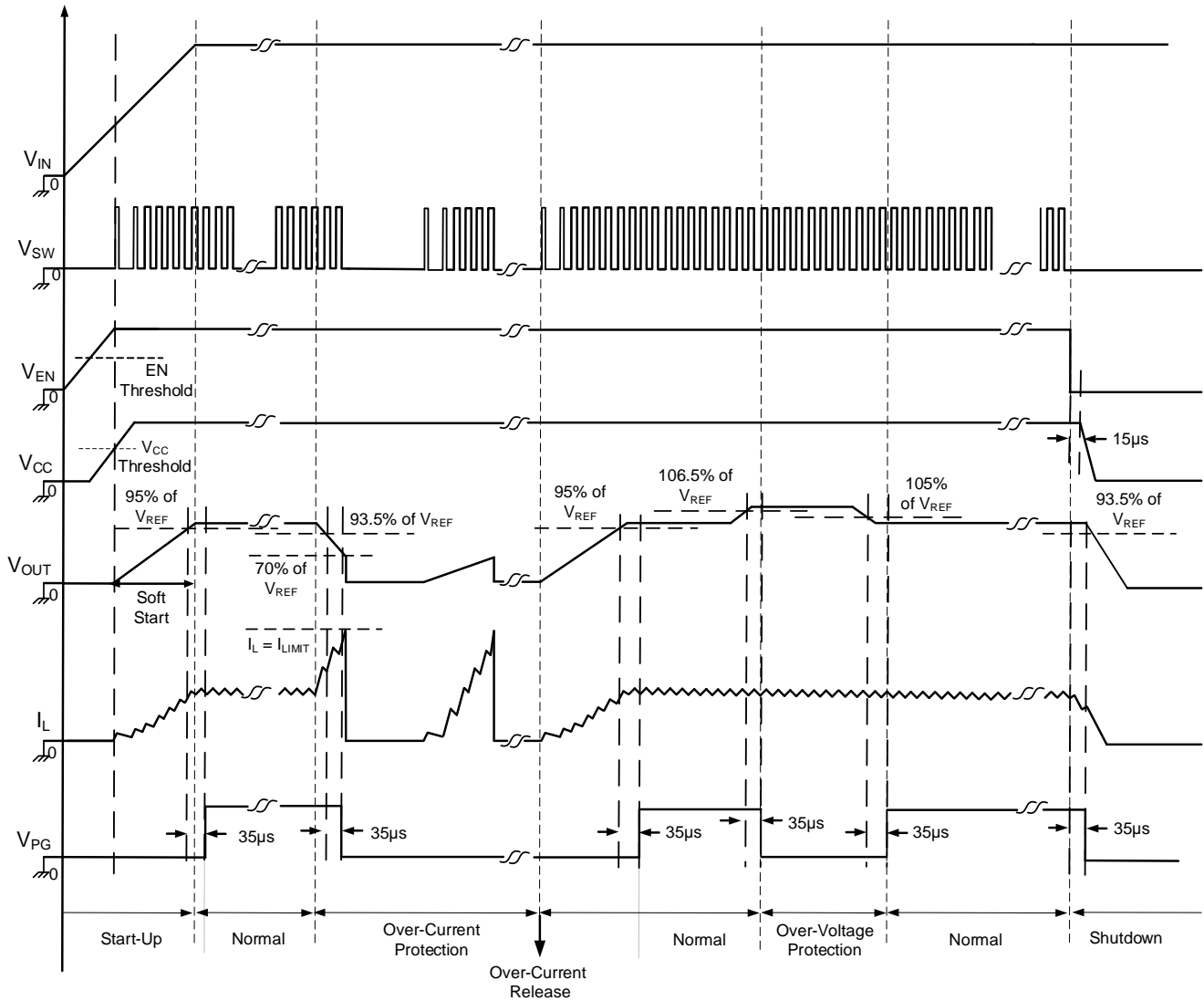


Figure 2: Timing Sequence

If MODE is pulled below 0.4V, then the MP4317 operates in AAM mode. AAM mode optimizes

OPERATION

The MP4317 is a synchronous, step-down switching converter with integrated internal power MOSFETs. It can achieve up to 7A of highly efficient, continuous output current (I_{OUT}) with current mode control for fast loop response.

The device features a wide 3.3V to 45V input voltage (V_{IN}) range, configurable switching frequency (f_{SW}), external soft start (SS), and precision current limiting. Its low 1.7 μ A shutdown current (I_{SD}) makes it well-suited for battery-powered applications.

Pulse-Width Modulation (PWM) Control

At moderate to high output currents, the MP4317 operates with a fixed frequency in peak current control mode to regulate the output voltage (V_{OUT}). A pulse-width modulation (PWM) cycle is initiated by the internal clock. At the rising edge of the clock, the high-side power MOSFET (HS-FET) turns on and remains on until its current reaches the value set by the internal comparator (V_{COMP}). The HS-FET remains on for a minimum of 100ns.

If the HS-FET is off, the low-side MOSFET (LS-FET) turns on and remains on until the next PWM cycle starts. The LS-FET remains on for a minimum of 80ns before the next cycle starts.

If the HS-FET current does not reach V_{COMP} within one PWM cycle, the HS-FET remains on to avoid shutting down the device. The HS-FET turns off after about 10 μ s, even if it has not reached V_{COMP} .

Light-Load Operation

The MP4317 has a mode selection pin (MODE) that selects the IC's operation mode at light loads. Under light-load conditions, the device can operate in either forced continuous conduction mode (FCCM) or advanced asynchronous modulation (AAM) mode.

If MODE is pulled above 1.8V, then the MP4317 operates in FCCM. The part works with fixed frequency from no load to full loads in this mode. Advantages of FCCM include the controllable fixed frequency and lower V_{OUT} ripple under light-load conditions.

efficiency under light-load and no-load conditions.

If AAM mode is enabled, then the MP4317 enters asynchronous operation as the inductor current (I_L) approaches 0A (see Figure 3). If the load decreases further or if there is no load, V_{COMP} drops to its set value and the device enters AAM mode.

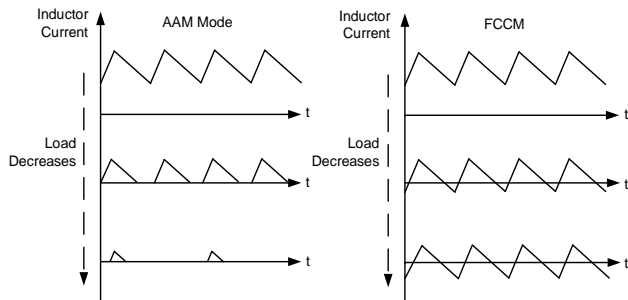


Figure 3: AAM Mode and FCCM

In AAM mode, the internal clock resets once V_{COMP} reaches its set value. The crossover time is used as the benchmark for the next clock. If

Bootstrap (BST) Charging

The internal bootstrap (BST) regulator charges and regulates the BST capacitor (C_{BST}) to about 5V. If the difference between the BST and SW pin voltages ($V_{BST} - V_{SW}$) drops below 5V, then a P-channel MOSFET pass transistor connected between the VCC and BST pins turns on to charge C_{BST} . The external circuit should provide enough voltage headroom to facilitate charging. If the HS-FET turns on, then V_{BST} exceeds the VCC voltage (V_{CC}) and C_{BST} cannot be charged.

At high duty cycles, there is less time to charge C_{BST} . This means that C_{BST} may not be charged sufficiently. If the external circuit has an insufficient voltage or not enough time to charge C_{BST} , then an additional external circuit is required to ensure that V_{BST} remains within its normal operation range.

Low-Dropout (LDO) Mode and Refreshing the Bootstrap Capacitor (C_{BST})

To improve dropout, the MP4317 is designed to operate at almost 100% duty cycle when $V_{BST} - V_{SW}$ exceeds 2.5V. If $V_{BST} - V_{SW}$ drops below 2.5V, then under-voltage lockout (UVLO) turns off the HS-FET. This allows the LS-FET to

the load increases and V_{COMP} exceeds its set value, then the device operates in discontinuous conduction mode (DCM) or FCCM, both of which have a constant f_{SW} .

Error Amplifier (EA)

The error amplifier (EA) compares the feedback (FB) voltage (V_{FB}) to the internal reference voltage (V_{REF}) (typically 0.815V), and outputs a current that is proportional to the difference between the two voltages. This I_{OUT} charges the compensation network to set V_{COMP} , which controls the power MOSFET's current.

During normal operation, the minimum V_{COMP} is 0.9V, and the maximum is 2V. If the IC shuts down, V_{COMP} is pulled down to AGND internally.

Internal Regulator (VCC)

The 4.9V internal regulator (VCC) powers most of the internal circuitry. The regulator uses the VIN pin as its input and operates across the entire V_{IN} range. If V_{IN} exceeds 4.9V, then VCC is in full regulation. If V_{IN} drops below 4.9V, then VCC's output degrades.

conduct and refresh the charge on C_{BST} . In DCM or pulse-skip mode (PSM), the LS-FET turns on to refresh V_{BST} .

Since the supply current sourced from C_{BST} is low, the HS-FET can remain on for more than the required switching cycles to refresh C_{BST} . As a result, the converter has a high effective duty cycle.

The converter's effective duty cycle during dropout is determined by the voltage drops across the HS-FET, the LS-FET, the inductor resistance, the low-side diode, and the PCB resistance.

Enable (EN) Control

Enable (EN) is a digital control pin that turns the converter on and off. Pull EN below 0.85V to turn the converter off; pull EN above 1V to turn it on.

Configurable V_{IN} Under-Voltage Lockout (UVLO) Protection

If V_{IN} exceeds the UVLO rising threshold, then the IC can be enabled and disabled via the EN pin. With an internal current source, a configurable V_{IN} UVLO threshold and hysteresis can be generated. The EN voltage (V_{EN}) can be

set via resistor dividers ($R_{EN1} + R_{EN2}$) (see Figure 4).

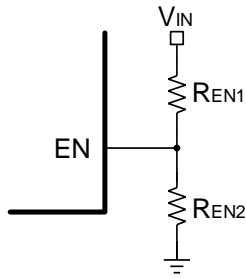


Figure 4: Enable Divider Circuit

Configurable Switching Frequency (f_{SW}) and Frequency Foldback

f_{SW} can be configured via an external resistor (R_{FREQ}) connected between the FREQ pin and AGND, or by a logic-level SYNC signal.

See the f_{SW} vs. R_{FREQ} curves on page 15 to select R_{FREQ} and set f_{SW} . If f_{SW} is set high, it may fold back at high input voltages to avoid triggering the minimum on time (t_{ON_MIN}) and forcing the output out of regulation.

Set f_{SW} between 350kHz and 1000kHz for car battery applications. Table 1 lists the recommended R_{FREQ} values for common switching frequencies. High frequencies can be used in applications that do not require a critical f_{SW} limit or that have a low, stable V_{IN} .

Table 1: R_{FREQ} vs. f_{SW}

| R_{FREQ} (k Ω) | f_{SW} (kHz) |
|--------------------------|----------------|
| 86.6 | 350 |
| 80.6 | 380 |
| 75 | 410 |
| 62 | 470 |
| 59 | 500 |
| 54.9 | 530 |
| 49.9 | 590 |
| 45.3 | 640 |
| 41.2 | 700 |
| 37.4 | 760 |
| 34 | 830 |
| 30.9 | 910 |
| 28.7 | 960 |
| 26.1 | 1000 |

Frequency Spread Spectrum (FSS)

The MP4317 employs a 12kHz modulation frequency and a fixed 128-step triangular profile to spread the internal f_{SW} across a 20% ($\pm 10\%$) window (see Figure 5). The steps are fixed and

independent of the set f_{SW} . This optimizes the frequency spread spectrum (FSS) performance.

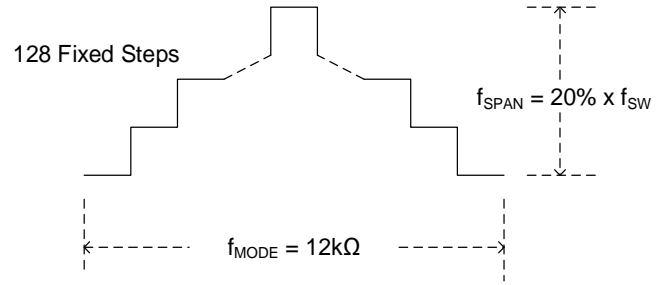


Figure 5: Spread Spectrum Scheme

Side bands are created by modulating f_{SW} via the triangle modulation waveform. This reduces the fundamental f_{SW} emission power and harmonics, which reduces noise caused by peak electromagnetic interference (EMI).

Soft Start (SS)

The MP4317 implements soft start (SS) to prevent V_{OUT} from overshooting during start-up.

Once SS is initiated, an internal current source charges the external soft-start capacitor (C_{SS}). If the soft-start voltage (V_{SS}) drops below V_{REF} , then V_{SS} overrides V_{REF} and the EA uses V_{SS} as the reference. If V_{SS} exceeds V_{REF} , then the EA uses V_{REF} as the reference.

The soft-start capacitance (C_{SS}) can be calculated with Equation (1):

$$C_{SS} \text{ (nF)} = \frac{t_{SS} \text{ (ms)} \times I_{SS} \text{ (\mu A)}}{V_{REF} \text{ (V)}} = 13.5 \times t_{SS} \text{ (ms)} \quad (1)$$

The SS pin can be used for tracking and sequencing.

Pre-Biased Start-Up

If V_{FB} exceeds $V_{SS} - 150\text{mV}$ during start-up, then the output has a pre-biased voltage. With a pre-biased voltage, the HS-FET and LS-FET do not turn on until V_{SS} exceeds V_{FB} .

Thermal Shutdown

Thermal shutdown prevents the IC from operating at exceedingly high temperatures. If the die temperature exceeds the thermal shutdown threshold (about 170°C), then the

device shuts down. Once the temperature drops below about 150°C, the device initiates a new SS and resumes normal operation.

Current Comparator and Current Limit

The MOSFET currents are sensed via a current-sense MOSFET. This current is fed to the high-speed current comparator for current mode control. The current comparator uses this sensed current as one of its inputs.

If the HS-FET turns on, the comparator is blanked until the end of the turn-on period to mitigate noise. The comparator compares the MOSFET current to the set V_{COMP} value. If the sensed current exceeds V_{COMP} , then the comparator outputs low to turn off the HS-FET. The internal MOSFET maximum current is limited internally cycle by cycle.

Output Over-Voltage Protection (OVP) with Hiccup Mode

If an output short to ground occurs, V_{OUT} may drop below 70% of its nominal value. If this occurs, the MP4317 shuts down to discharge C_{SS} . Once C_{SS} is discharged, the device initiates

Power Good (PG) Output

The power good (PG) pin is an open-drain output. If using the PG pin, connect it to a power source via a pull-up resistor. If V_{OUT} is between 95% and 105% of the nominal voltage, then PG is pulled high. If V_{OUT} exceeds 106.5% or drops below 93.5% of the nominal voltage, then PG is pulled low.

SYNCIN and SYNCO

f_{SW} can be synchronized to the rising edge of the SYNCIN clock. It is recommended that the SYNCIN frequency (f_{SYNCIN}) be between 350kHz and 1000kHz. SYNCIN's off time (t_{OFF}) should be shorter than the internal oscillator period; otherwise, the internal clock may turn on the HS-FET before the rising edge of SYNCIN.

There is no SYNCIN pulse width limit; however, there is always parasitic capacitance on the pad. If the pulse width is too short, then a clear rising

a SS to resume normal operation. This process repeats until the fault condition is removed.

Start-Up and Shutdown

If both V_{IN} and V_{EN} exceed their respective thresholds, the MP4317 starts up. The reference block starts up first to generate a stable V_{REF} and currents. Then the internal regulator starts up to provide a stable supply for the remaining circuitries.

While the internal supply rail is up, an internal timer turns the HS-FET and LS-FET off for about 50 μ s to blank any start-up glitches. Once the soft-start block is enabled, the device outputs low to ensure that the remaining circuitry is ready before slowly ramping up.

Three events can shut down the IC: V_{EN} going low, V_{IN} going low, and thermal shutdown. Once shutdown is initiated, the signaling path is blocked to avoid triggering any faults. Then V_{COMP} and the internal supply rail are pulled down. The floating driver is not subject to this shutdown command, but its charging path is disabled.

and falling edge may not be achieved due to the parasitic capacitance. It is recommended to set the pulse width above 100ns.

If using SYNCIN in AAM mode, pull SYNCIN below 0.4V or float SYNCIN before start-up and then add the external SYNCIN clock. Connect a 10k Ω to 51k Ω resistor between SYNCIN and AGND to avoid floating SYNCIN.

The SYNCO pin provides a default 180° phase-shifted clock for the internal oscillator. If there is not an external SYNCIN clock, then SYNCO provides a 180° phase-shifted clock that is compared to the internal clock. If there is an external SYNCIN clock, then SYNCO provides a 180° phase-shifted clock that is compared to the external SYNCIN clock.

APPLICATION INFORMATION

Setting the Output Voltage

The external resistor divider connected to the FB pin sets V_{OUT} (see Figure 6).

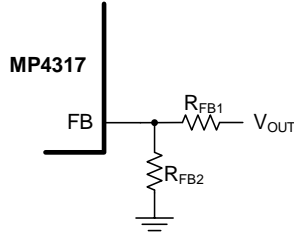


Figure 6: Feedback Network

The feedback resistance (R_{FB2}) can be calculated with Equation (2):

$$R_{FB2} = \frac{R_{FB1}}{\frac{V_{OUT}}{0.815V} - 1} \quad (2)$$

Table 2 lists the recommended feedback resistor values for common output voltages.

Table 2: Recommended Resistor Values for Common Output Voltages

| V _{OUT} (V) | R _{FB1} (kΩ) | R _{FB2} (kΩ) |
|----------------------|-----------------------|-----------------------|
| 3.3 | 100 (1%) | 32.4 (1%) |
| 5 | 100 (1%) | 19.6 (1%) |

Selecting the Input Capacitor (C_{IN})

The step-down converter has a discontinuous input current, and requires a capacitor to supply AC current to the converter while maintaining the DC V_{IN}. For the best performance, use low-ESR capacitors. Ceramic capacitors with X5R or X7R dielectrics are highly recommended due to their low ESR and small temperature coefficients. For most applications, a 4.7μF to 10μF capacitor is sufficient. It is strongly recommended to use another, lower-value capacitor (0.1μF) with a small package size (0603) to absorb high-frequency noise. Place the smaller capacitor as close to the VIN pin and PGND as possible.

Since the input capacitor (C_{IN}) absorbs the input switching current, it requires an adequate ripple current rating. Estimate the RMS current in C_{IN} (I_{CIN}) with Equation (3):

$$I_{CIN} = I_{LOAD} \times \sqrt{\frac{V_{OUT}}{V_{IN}} \times \left(1 - \frac{V_{OUT}}{V_{IN}}\right)} \quad (3)$$

The worst-case condition occurs at V_{IN} = 2 × V_{OUT}, which can be calculated with Equation (4):

$$I_{CIN} = \frac{I_{LOAD}}{2} \quad (4)$$

For simplification, choose a C_{IN} with an RMS current rating greater than half of the maximum load current (I_{LOAD_MAX}).

C_{IN} can be electrolytic, tantalum, or ceramic. If using electrolytic or tantalum capacitors, place a small, high-quality ceramic capacitor (0.1μF) as close to the device as possible.

The input capacitance determines the input voltage ripple of the converter. If using ceramic capacitors, ensure that C_{IN} meets the system design's input voltage ripple (ΔV_{IN}) requirement. C_{IN} should have enough capacitance to provide a sufficient charge to prevent an excessive voltage ripple at the input. The input voltage ripple (ΔV_{IN}) caused by the capacitance can be estimated with Equation (5):

$$\Delta V_{IN} = \frac{I_{LOAD}}{f_{SW} \times C_{IN}} \times \frac{V_{OUT}}{V_{IN}} \times \left(1 - \frac{V_{OUT}}{V_{IN}}\right) \quad (5)$$

Selecting the Output Capacitor (C_{OUT})

The output capacitor (C_{OUT}) maintains the DC V_{OUT}. Use ceramic, tantalum, or low-ESR electrolytic capacitors. Ceramic capacitors with low ESR are recommended for their small size and low output voltage ripple. The output voltage ripple (ΔV_{OUT}) can be calculated with Equation (6):

$$\Delta V_{OUT} = \frac{V_{OUT}}{f_{SW} \times L} \times \left(1 - \frac{V_{OUT}}{V_{IN}}\right) \times \left(R_{ESR} + \frac{1}{8 \times f_{SW} \times C_{OUT}}\right) \quad (6)$$

Where L is the inductance, and R_{ESR} is the equivalent series resistance of C_{OUT}.

For ceramic capacitors, the capacitance dominates the impedance at f_{SW} and causes the majority of ΔV_{OUT}. For simplification, the output voltage ripple (ΔV_{OUT}) can be estimated with Equation (7):

$$\Delta V_{OUT} = \frac{V_{OUT}}{8 \times f_{SW}^2 \times L \times C_{OUT}} \times \left(1 - \frac{V_{OUT}}{V_{IN}}\right) \quad (7)$$

For tantalum or electrolytic capacitors, the ESR dominates the impedance at f_{SW} . For simplification, ΔV_{OUT} can be estimated with Equation (8):

$$\Delta V_{OUT} = \frac{V_{OUT}}{f_{SW} \times L} \times \left(1 - \frac{V_{OUT}}{V_{IN}}\right) \times R_{ESR} \quad (8)$$

The characteristics of C_{OUT} also affect the stability of the regulation system. The MP4317 can be optimized for a wide range of capacitances and ESR values.

Selecting the Inductor

For most applications, a $1\mu\text{H}$ to $10\mu\text{H}$ inductor with a DC current rating of at least 25% greater than I_{LOAD_MAX} is recommended. For higher efficiency, choose an inductor with a lower DC resistance. A larger-value inductor offers less ripple current and a lower ΔV_{OUT} ; however, a larger-value inductor also has a larger physical size, higher series resistance, and lower saturation current. A good rule to determine the inductance is to allow the inductor ripple current (ΔI_L) to be approximately 30% of I_{LOAD_MAX} . Estimate the inductance (L) with Equation (9):

$$L = \frac{V_{OUT}}{f_{SW} \times \Delta I_L} \times \left(1 - \frac{V_{OUT}}{V_{IN}}\right) \quad (9)$$

Choose ΔI_L to be about 30% of I_{LOAD_MAX} . The maximum inductor peak current (I_{LP}) can be calculated with Equation (10):

$$I_{LP} = I_{LOAD} + \frac{V_{OUT}}{2 \times f_{SW} \times L} \times \left(1 - \frac{V_{OUT}}{V_{IN}}\right) \quad (10)$$

Setting the V_{IN} Under-Voltage Lockout (UVLO) Threshold

The MP4317 has an internal, fixed UVLO threshold. The rising threshold is 3V, and the falling threshold is about 2.7V. For applications that require a higher UVLO, place an external resistor divider between the V_{IN} and EN pins to raise the UVLO threshold (see Figure 7).

The UVLO rising threshold ($V_{IN_UVLO_RISING}$) can be calculated with Equation (11):

$$V_{IN_UVLO_RISING} = \left(1 + \frac{R_{UP}}{R_{DOWN}}\right) \times V_{EN_RISING} \quad (11)$$

Where V_{EN_RISING} is 1V.

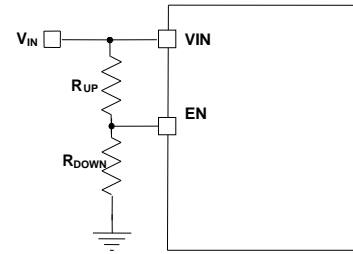


Figure 7: Adjustable UVLO Using EN Divider

The UVLO falling threshold ($V_{IN_UVLO_FALLING}$) can be calculated with Equation (12):

$$V_{IN_UVLO_FALLING} = \left(1 + \frac{R_{UP}}{R_{DOWN}}\right) \times V_{EN_FALLING} \quad (12)$$

Where $V_{EN_FALLING}$ is 0.85V.

Selecting the External Bootstrap (BST) Diode and Resistor

An external BST diode can enhance the BST regulator's efficiency during high duty cycles. A 2.5V to 5V power supply can be used to power the external BST diode. It is recommended to use V_{CC} or V_{OUT} as the power supply (see Figure 8).

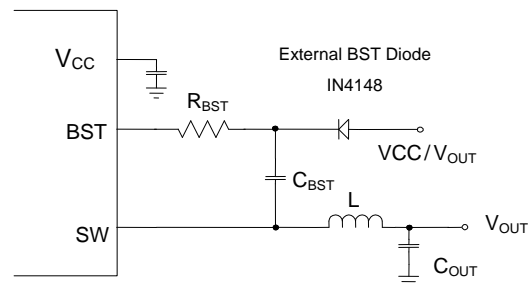


Figure 8: Optional External BST Diode for Enhanced Efficiency

It is recommended to use an IN4148 external BST diode. $1\mu\text{F}$. A resistor (R_{BST}) in series with C_{BST} can reduce the V_{SW} rising slew rate and voltage spikes. This improves EMI performance and reduces voltage stress at high input voltages. A higher resistance is better for SW spike reduction, but can compromise efficiency. To make a tradeoff between EMI and efficiency, it is recommended to keep R_{BST} below 20Ω . The recommended C_{BST} value is $0.1\mu\text{F}$ to $1\mu\text{F}$.

Selecting the VCC Capacitor (C_{VCC})

The V_{CC} capacitance (C_{VCC}) should be 10 times the boost capacitor's capacitance. C_{VCC} should not exceed $68\mu\text{F}$.

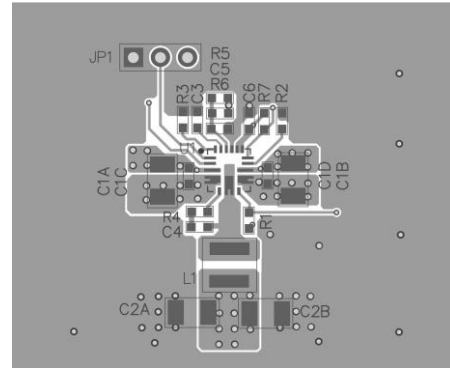
PCB Layout Guidelines ⁽¹⁰⁾

Efficient PCB layout is critical for stable operation. It is recommended to use a 4-layer layout to improve thermal performance. For the best results, refer to Figure 9 and follow the guidelines below:

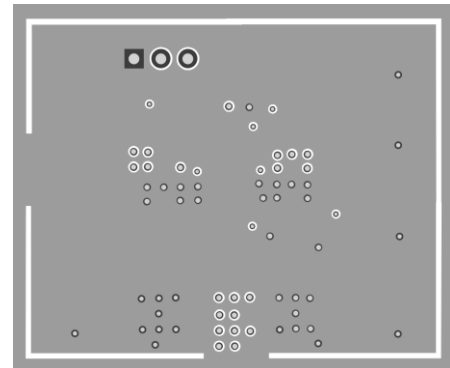
1. Place the symmetric input capacitors as close to VIN and PGND as possible.
2. Connect a large copper plane directly to PGND.
3. If the bottom PCB layer is the ground plane, place multiple vias near PGND.
4. Use short, direct, and wide traces for the high-current paths connected to VIN and PGND.
5. Place C_{IN} as close to the VIN and PGND pins as possible to minimize high-frequency noise. It is recommended that C_{IN} be a ceramic bypass capacitor in a small 0603 package.
6. Keep the connection between C_{IN} and VIN as short and wide as possible.
7. Place C_{VCC} as close to VCC and AGND as possible.
8. Route the SW and BST traces away from sensitive analog areas, such as FB.
9. Keep the FB trace as short as wide as possible by placing the FB resistors close to the IC.
10. Use multiple vias to connect the power planes and the internal layers.

Note:

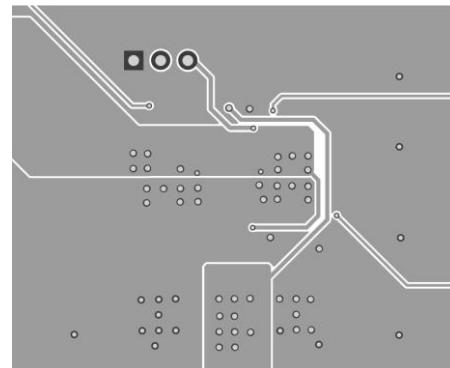
- 10) The recommended PCB layout is based on Figure 10 on page 34.



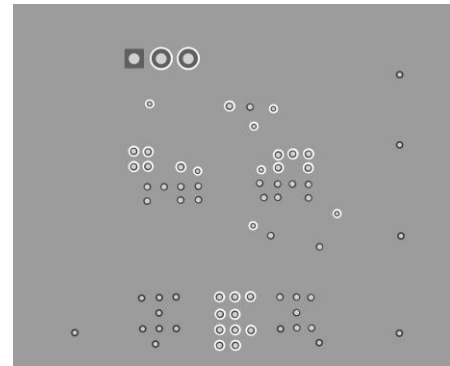
Top Layer



Mid-Layer 1



Mid-Layer 2



Bottom Layer

Figure 9: Recommended PCB Layout

TYPICAL APPLICATION CIRCUITS

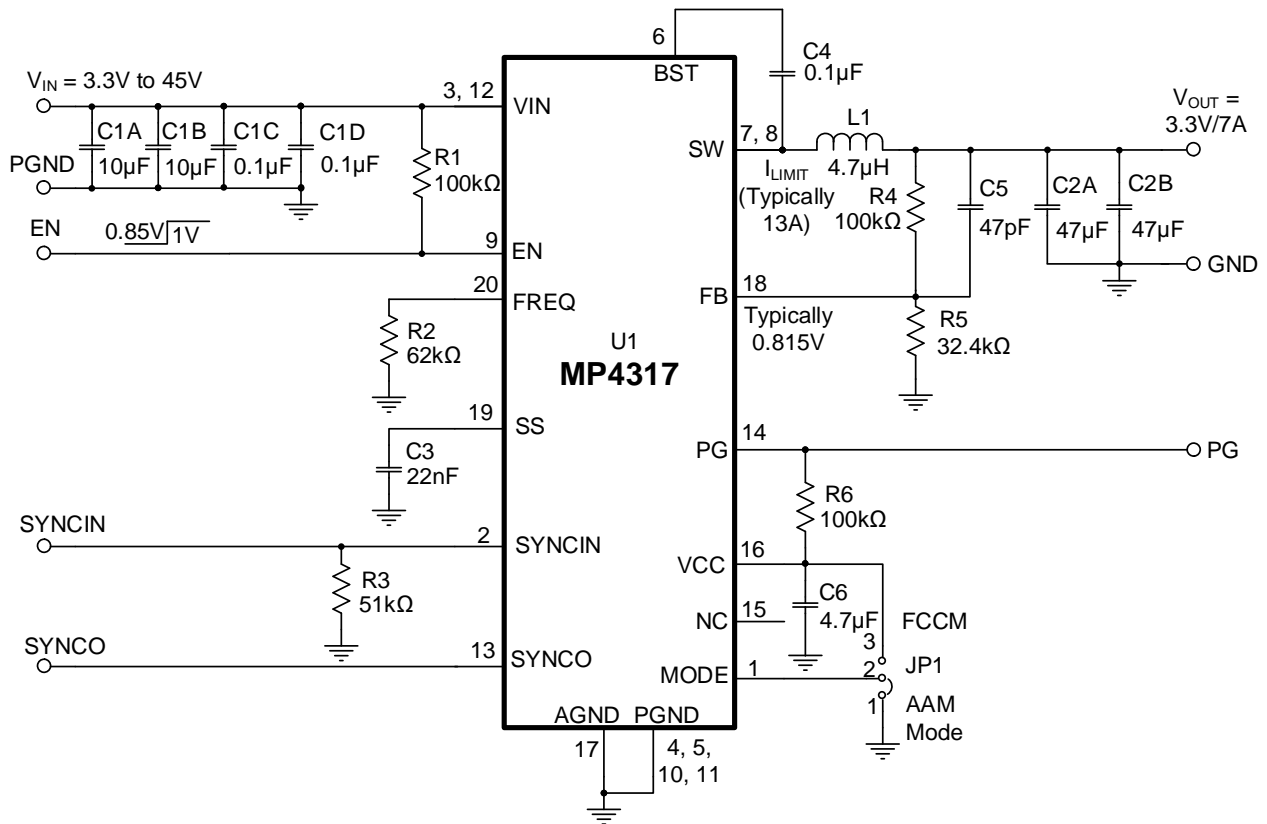


Figure 10: Typical Application Circuit ($V_{OUT} = 3.3V$, $f_{sw} = 470kHz$)

TYPICAL APPLICATION CIRCUITS (continued)

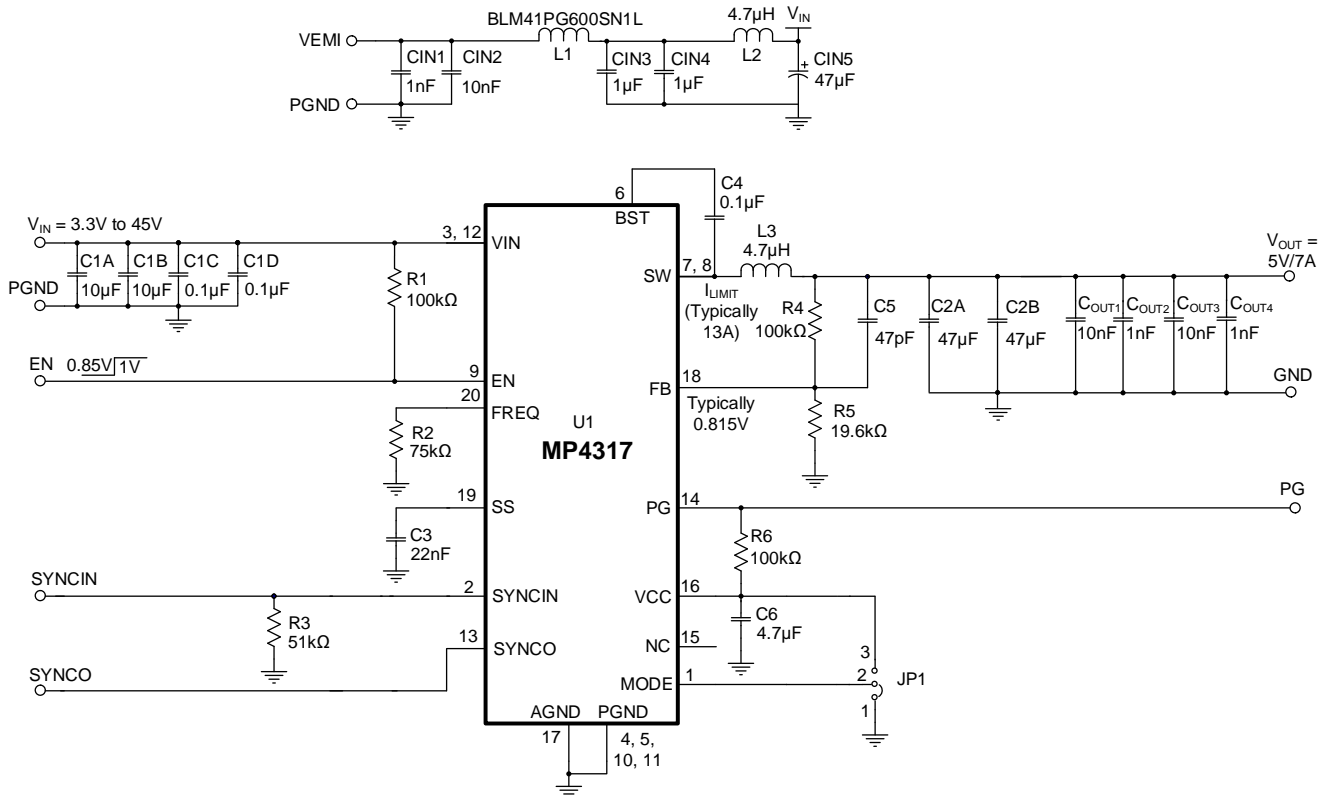
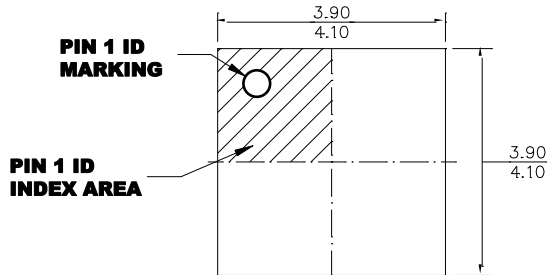


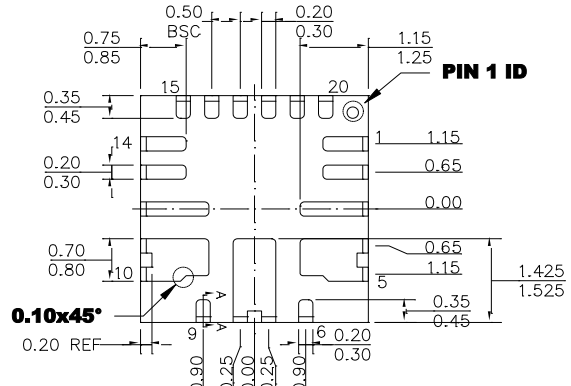
Figure 11: Typical Application Circuit ($V_{OUT} = 5V$, $f_{sw} = 410kHz$, with EMI Filters)

PACKAGE INFORMATION

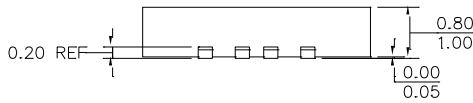
QFN-20 (4mmx4mm) Wettable Flank



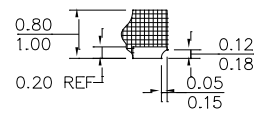
TOP VIEW



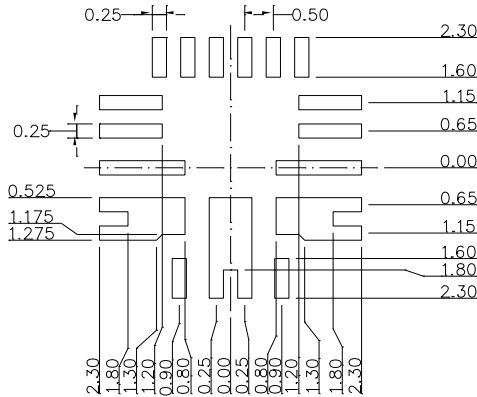
BOTTOM VIEW



SIDE VIEW



SECTION A-A

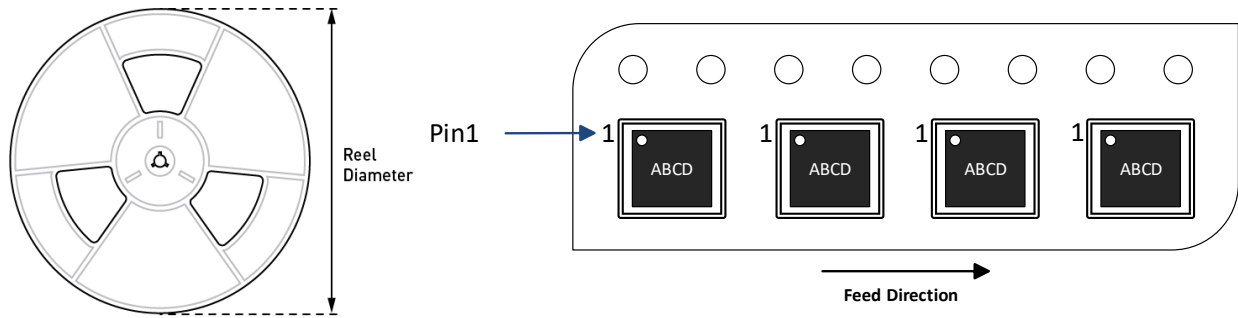


RECOMMENDED LAND PATTERN

NOTE:

- 1) THE LEAD SIDE IS WETTABLE.
- 2) ALL DIMENSIONS ARE IN MILLIMETERS.
- 3) LEAD COPLANARITY SHALL BE 0.08 MILLIMETERS MAX.
- 4) JEDEC REFERENCE IS MO-220.
- 5) DRAWING IS NOT TO SCALE.

CARRIER INFORMATION



| Part Number | Package Description | Quantity/ Reel | Quantity/ Tube ⁽¹¹⁾ | Reel Diameter | Carrier Tape Width | Carrier Tape Pitch |
|-------------|---------------------|----------------|--------------------------------|---------------|--------------------|--------------------|
| MP4317GRE-Z | QFN-20 (4mmx4mm) | 5000 | N/A | 13in | 12mm | 8mm |

Note:

11) N/A indicates "not available" in tubes. For 500-piece tape & reel prototype quantities, contact MPS. (The order code for a 500-piece partial reel is "-P". Tape & reel dimensions are the same as for full reel.)



REVISION HISTORY

| Revision # | Revision Date | Description | Pages Updated |
|------------|---------------|-----------------|---------------|
| 1.0 | 9/24/2021 | Initial Release | - |

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